

# System-Side Impedance Track™ Fuel Gauge With Integrated LDO

Check for Samples: bq27520-G1

### 1 INTRODUCTION

### 1.1 FEATURES

- Battery Fuel Gauge for 1-Series Li-Ion Applications
- Resides on System Main Board
  - Works With Embedded or Removable Battery Packs
- Uses PACK+, PACK-, and T Battery Terminals
- Microcontroller Peripheral Provides:
  - Accurate Battery Fuel Gauging
  - Internal Temperature Sensor for Battery Temperature Reporting
  - Battery Low Interrupt Warning
  - Battery Insertion Indicator
  - Configurable Level of State of Charge (SOC) Interrupts
  - State of Health Indicator
  - Current Data Logging Buffer
  - 96 Bytes of Non-Volatile Scratch-Pad FLASH
- Battery Fuel Gauge Based on Patented Impedance Track™ Technology
  - Models the Battery Discharge Curve for Accurate Time-to-Empty Predictions
  - Automatically Adjusts for Battery Aging, Battery Self-Discharge, and Temperature/Rate Inefficiencies
  - Low-Value Sense Resistor (10 mΩ or Less)
- 400-kHz I<sup>2</sup>C<sup>™</sup> Interface for Connection to System Microcontroller Port
- In a 15-Pin NanoFree<sup>™</sup> (CSP) Packaging

### 1.2 APPLICATIONS

- Smartphones
- PDAs
- Digital Still and Video Cameras
- Handheld Terminals
- MP3 or Multimedia Players

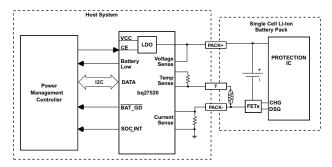
### 1.3 DESCRIPTION

The Texas Instruments bq27520-G1 system-side Li-lon battery fuel gauge is a microcontroller peripheral that provides fuel gauging for single-cell Li-lon battery packs. The device requires little system microcontroller firmware development. The bq27520-G1 resides on the system's main board and manages an embedded battery (non-removable) or a removable battery pack.

The bq27520-G1 uses the patented Impedance Track™ algorithm for fuel gauging, and provides information such as remaining battery capacity (mAh), state-of-charge (%), run-time to empty (min), battery voltage (mV), temperature (°C) and state of health (%).

Battery fuel gauging with the bq27520-G1 requires only PACK+ (P+), PACK- (P-), and Thermistor (T) connections to a removable battery pack or embedded battery circuit. The CSP option is a 15-ball package in the dimensions of 2,61 mm × 1,96 mm with 0,5 mm lead pitch. It is ideal for space constrained applications.

#### TYPICAL APPLICATION



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Impedance Track, NanoFree are trademarks of Texas Instruments. I<sup>2</sup>C is a trademark of NXP B.V. Corp Netherlands.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

1	INTR	ODUCTION 1	<u> </u>	4.3	MANUFACTURER INFORMATION BLOCKS	21
	1.1	FEATURES 1	<u>l</u>	4.4	ACCESS MODES	22
	1.2	APPLICATIONS 1	<u> </u>	4.5	SEALING/UNSEALING DATA FLASH	22
2	1.3 <b>DEVI</b>	DESCRIPTION 1 ICE INFORMATION 3	_	4.6 <b>FUN</b>	DATA FLASH SUMMARY CTIONAL DESCRIPTION	
	2.1	AVAILABLE OPTIONS	3	5.1	FUEL GAUGING	25
	2.2	THERMAL INFORMATION	3	5.2	IMPEDANCE TRACK™ VARIABLES	_
	2.3	PIN ASSIGNMENT	3	5.3	DETAILED PIN DESCRIPTION	28
3	ELEC	CTRICAL SPECIFICATIONS5	<u>5</u>	5.4	TEMPERATURE MEASUREMENT	_
	3.1	ABSOLUTE MAXIMUM RATINGS	5	5.5	OVERTEMPERATURE INDICATION	33
	3.2	RECOMMENDED OPERATING CONDITIONS 5	5	5.6	CHARGING AND CHARGE-TERMINATION INDICATION	33
	3.3	POWER-ON RESET	<u> </u>	5.7	POWER MODES	
	3.4	2.5V LDO REGULATOR	<u> </u>	5.8	POWER CONTROL	35
	3.5	INTERNAL TEMPERATURE SENSOR		5.9	AUTOCALIBRATION	36
		CHARACTERISTICS	- 0	APP	LICATION-SPECIFIC INFORMATION	36
	3.6	HIGH-FREQUENCY OSCILLATOR	<u> </u>	6.1	BATTERY PROFILE STORAGE AND SELECTION	
	3.7	LOW-FREQUENCY OSCILLATOR	<del>7</del> -	62	APPLICATION-SPECIFIC FLOW AND CONTROL	36
	3.8	INTEGRATING ADC (COULOMB COUNTER) CHARACTERISTICS	7	0.2	THE PROPERTY OF LOW OF LOW YORK CONTINUES.	37
	3.9	ADC (TEMPERATURE AND CELL	7	COM	MMUNICATIONS	
		MEASUREMENT) CHARACTERISTICS	7_	7.1	I <sup>2</sup> C INTERFACE	
	3.10	DATA FLASH MEMORY CHARACTERISTICS 8	<u>3</u>	7.2	I <sup>2</sup> C Time Out	
	3.11	I <sup>2</sup> C-COMPATIBLE INTERFACE COMMUNICATION		7.3	I <sup>2</sup> C Command Waiting Time	
		TIMING CHARACTERISTICS	- 0	REF	ERENCE SCHEMATICS	
4		ERAL DESCRIPTION	_	8.1	SCHEMATIC	
	4.1 4.2	DATA COMMANDS         10           DATA FLASH INTERFACE         20	_	8.2	Package Dimensions	
	4.2	DATA FLAGITINI ERFACE	<u>,                                    </u>			



SL<u>US955-JUNE 2010</u> www.ti.com

### **DEVICE INFORMATION**

### **AVAILABLE OPTIONS**

PART NUMBER	FIRMWARE VERSION	PACKAGE <sup>(1)</sup>	T <sub>A</sub>	COMMUNICATION FORMAT	TAPE and REEL QUANTITY
bq27520YZFR-G1	2.04	CCD 45	40°C to 05°C	I <sup>2</sup> C	3000
bq27520YZFT-G1	3.01	CSP-15	–40°C to 85°C	I-C	250

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

#### THERMAL INFORMATION 2.2

	THERMAL METRIC <sup>(1)</sup>	bq27520-G1	LINUTO
	THERMAL METRIC**	YZF (15 PINS)	UNITS
$\theta_{JA}$	Junction-to-ambient thermal resistance	70	
$\theta_{\text{JC(top)}}$	Junction-to-case(top) thermal resistance	17	
$\theta_{JB}$	Junction-to-board thermal resistance	20	°C/W
ΨЈТ	Junction-to-top characterization parameter	1	C/VV
ΨЈВ	Junction-to-board characterization parameter	18	
$\theta_{\text{JC(bottom)}}$	Junction-to-case(bottom) thermal resistance	n/a	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

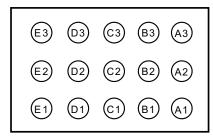
Submit Documentation Feedback Product Folder Link(s): bq27520-G1

#### 2.3 **PIN ASSIGNMENT**

CSP-15 (TOP VIEW)



CSP-15 (BOTTOM VIEW)



TEXAS INSTRUMENTS

SLUS955-JUNE 2010 www.ti.com

## **Table 2-1. PIN FUNCTIONS**

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME NO.		IYPE	DESCRIPTION
SRP	A1	IA	Analog input pin connected to the internal coulomb counter where SRP is nearest the PACK– connection. Connect to $5\text{-m}\Omega$ to $20\text{-m}\Omega$ sense resistor.
SRN	B1	IA	Analog input pin connected to the internal coulomb counter where SRN is nearest the Vss connection. Connect to $5\text{-m}\Omega$ to $20\text{-m}\Omega$ sense resistor.
V <sub>SS</sub>	C1, C2	Р	Device ground
V <sub>CC</sub>	D1	Р	Regulator output and bq27520-G1 processor power. Decouple with 1μF ceramic capacitor to Vss.
REGIN	E1	Р	Regulator input. Decouple with 0.1µF ceramic capacitor to Vss.
SOC_INT	A2	I/O	SOC state interrupts output. Generate a pulse under the conditions specified by Table 5-6. Open drain output. (RA3)
BAT_GD	B2	0	Battery-good indicator. Active-low by default, though polarity can be configured through the [BATG_POL] bit of <b>Operation Configuration</b> . Push-pull output. (RC1)
CE	D2	ı	Chip Enable. Internal LDO is disconnected from REGIN when driven low.
BAT	E2	I	Cell-voltage measurement input. ADC input. Recommend 4.8V maximum for conversion accuracy. (RC3)
SCL	А3	Ι	Slave I <sup>2</sup> C serial communications clock input line for communication with system (Master). Use with 10kΩ pull-up resistor (typical). (RA2)
SDA	В3	I/O	Slave I <sup>2</sup> C serial communications data line for communication with system (Master). Open-drain I/O. Use with 10kΩ pull-up resistor (typical). (RA1)
BAT_LOW	С3	0	Battery Low output indicator. Active <i>high</i> by default, though polarity can be configured through the [BATL_POL] bit of <i>Operation Configuration</i> . Push-pull output. (RC0)
TS	D3	IA	Pack thermistor voltage sense (use 103AT-type thermistor). ADC input. (RC2)
BI/TOUT	E3	I/O	Battery-insertion detection input. Power pin for pack thermistor network. Thermistor-multiplexer control pin. Use with pull-up resistor >1 $M\Omega$ (1.8 $M\Omega$ typical). (RA0)

<sup>(1)</sup> I/O = Digital input/output, IA = Analog input, P = Power connection



### 3 ELECTRICAL SPECIFICATIONS

### 3.1 ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

	PARAMETER	VALUE	UNIT
V <sub>REGIN</sub>	Regulator input range	-0.3 to 5.5	V
$V_{CC}$	Supply voltage range	-0.3 to 2.75	V
$V_{IOD}$	Open-drain I/O pins (SDA, SCL, SOC_INT)	-0.3 to 5.5	V
$V_{BAT}$	BAT input pin	-0.3 to 5.5	
VI	Input voltage range to all other pins (BI/TOUT, TS, SRP, SRN, BAT_GD)	-0.3 to V <sub>CC</sub> + 0.3	V
	Human-body model (HBM), BAT pin	1.5	1-1/
ESD	Human-body model (HBM), all other pins	2	kV
T <sub>A</sub>	Operating free-air temperature range	-40 to 85	°C
T <sub>F</sub>	Functional temperature range	-40 to 100	°C
T <sub>stg</sub>	Storage temperature range	-65 to 150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 3.2 RECOMMENDED OPERATING CONDITIONS

 $T_A = 25$ °C and  $V_{REGIN} = V_{BAT} = 3.6V$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
\ /	Complex on the ma	No operating restrictions	2.7		4.5	V
$V_{REGIN}$	Supply voltage	No FLASH writes	2.45		2.7	V
C <sub>REGIN</sub>	External input capacitor for internal LDO between REGIN and $\rm V_{SS}$	Nominal capacitor values specified.  Recommend a 5% ceramic X5R type		0.1		μF
C <sub>LDO25</sub>	External output capacitor for internal LDO between $V_{\text{CC}}$ and $V_{\text{SS}}$	capacitor located close to the device.	0.47	1		μF
I <sub>CC</sub>	Normal operating-mode current <sup>(1)</sup>	Fuel gauge in NORMAL mode. I <sub>LOAD</sub> > Sleep Current		118		μΑ
I <sub>SLP+</sub>	Sleep+ operating mode current <sup>(1)</sup>	Fuel gauge in SLEEP+ mode. I <sub>LOAD</sub> < Sleep Current		62		μА
I <sub>SLP</sub>	Low-power storage-mode current <sup>(1)</sup>	Fuel gauge in SLEEP mode. I <sub>LOAD</sub> < Sleep Current		23		μΑ
I <sub>HIB</sub>	Hibernate operating-mode current <sup>(1)</sup>	Fuel gauge in HIBERNATE mode. I <sub>LOAD</sub> < <i>Hibernate Current</i>		8		μА
V <sub>OL</sub>	Output voltage, low (SCL, SDA, SOC_INT, BAT_LOW)	I <sub>OL</sub> = 3 mA			0.4	٧
V <sub>OH(PP)</sub>	Output voltage, high (BAT_LOW, BAT_GD)	I <sub>OH</sub> = -1 mA	V <sub>CC</sub> - 0.5			V
V <sub>OH(OD)</sub>	Output voltage, high (SDA, SCL, SOC_INT)	External pullup resistor connected to V <sub>CC</sub>	V <sub>CC</sub> - 0.5			V
V	Input voltage, low (SDA, SCL)		-0.3		0.6	
$V_{IL}$	Input voltage, low (BI/TOUT)	BAT INSERT CHECK MODE active	-0.3		0.6	
	Input voltage, high (SDA, SCL)		1.2		6	V
$V_{IH(OD)}$	Input voltage, high (BI/TOUT)	BAT INSERT CHECK MODE active	1.2		V <sub>CC</sub> + 0.3	
V <sub>A1</sub>	Input voltage range (TS)		V <sub>SS</sub> - 0.125		2	V
V <sub>A2</sub>	Input voltage range (BAT)		V <sub>SS</sub> - 0.125		5	V
V <sub>A3</sub>	Input voltage range (SRP, SRN)		V <sub>SS</sub> - 0.125		0.125	V
I <sub>lkg</sub>	Input leakage current (I/O pins)				0.3	μА
t <sub>PUCD</sub>	Power-up communication delay			250		ms

<sup>(1)</sup> Specified by design. Not production tested.



### 3.3 POWER-ON RESET

 $T_A = -40$ °C to 85°C, typical values at  $T_A = 25$ °C and  $V_{REGIN} = 3.6$  V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{IT+}$	Positive-going battery voltage input at V <sub>CC</sub>		2.09	2.20	2.31	٧
V <sub>HYS</sub>	Power-on reset hysteresis		45	115	185	mV

### 3.4 2.5V LDO REGULATOR

=  $1\mu F$   $V_{PEOM} = 3.6V$  (unless otherwise noted)

	PARAMETER	TEST CONDITIO	N.	MIN	NOM	MAX	UNIT
		TEST CONDITIO	'IN	IVIIIV	NOW	IVIAA	UNIT
2.5 V LDO RI	EGULATOR <sup>(1)</sup>						
		$2.7V \le V_{REGIN} \le 4.5V$ , $I_{OUT} \le 16mA$	$T_A = -40$ °C to 85°C	2.4	2.5	2.54	V
V <sub>REG25</sub>	Regulator output voltage	$2.45V \le V_{REGIN} < 2.7V$ (low battery), $I_{OUT} \le 3mA$	$T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	2.4			V
V <sub>IH(CE)</sub>	CE High-level input voltage	VREGIN = 2.7 to 4.5V					V
$V_{IL(CE)}$	CE Low-level input voltage	VREGIN = 2.7 to 4.5V	$T_A = -40$ °C to 85°C				V
M	Degulator drangut valtage	2.7V, I <sub>OUT</sub> ≤ 16mA	$T_A = -40$ °C to 85°C			325	m)/
$V_{DO}$	Regulator dropout voltage	2.45V, I <sub>OUT</sub> ≤ 3mA	$T_A = -40$ °C to 85°C			50	mV
$\Delta V_{REGTEMP}$	Regulator output change with temperature	V <sub>REGIN</sub> = 3.6V, I <sub>OUT</sub> = 16mA	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$		0.5%		
$\Delta V_{REGLINE}$	Line regulation	2.7V ≤ V <sub>REGIN</sub> ≤ 4.5V, I <sub>OUT</sub> = 16mA			18	40	mV
ΔV <sub>REGLOAD</sub> Load regulation		$0.2\text{mA} \le I_{\text{OUT}} \le 3\text{mA}, V_{\text{REGIN}} = 2.45 \text{ V}$			34	40	m)/
		3mA ≤ I <sub>OUT</sub> ≤ 16mA, V <sub>REGIN</sub> = 2.7 V			31		mV
I <sub>SHORT</sub> (2)	Short circuit current limit	V <sub>REG25</sub> = 0V	$T_A = -40$ °C to 85°C			250	mA

<sup>(1)</sup> LDO output current,  $I_{OUT}$ , is the sum of internal and external load currents. (2) Assured by design. Not production tested.

### INTERNAL TEMPERATURE SENSOR CHARACTERISTICS

 $T_A = -40$ °C to 85°C, 2.4 V <  $V_{CC}$  < 2.6 V; typical values at  $T_A = 25$ °C and  $V_{CC} = 2.5$  V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G <sub>TEMP</sub>	Temperature sensor voltage gain			-2		mV/°C

### HIGH-FREQUENCY OSCILLATOR

 $T_A = -40$ °C to 85°C, 2.4 V <  $V_{CC}$  < 2.6 V; typical values at  $T_A = 25$ °C and  $V_{CC} = 2.5$  V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
fosc	Operating frequency			2.097		MHz
		T <sub>A</sub> = 0°C to 60°C	-2%	0.38%	2%	
$f_{EIO}$	Frequency error <sup>(1)</sup> (2)	$T_A = -20$ °C to $70$ °C	-3%	0.38%	3%	
		$T_A = -40$ °C to 85°C	-4.5%	0.38%	4.5%	
t <sub>SXO</sub>	Start-up time <sup>(3)</sup>			2.5	5	ms

The frequency error is measured from 2.097 MHz.

The frequency drift is included and measured from the trimmed frequency at  $V_{CC} = 2.5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

The start-up time is defined as the time it takes for the oscillator output frequency to be within ±3% of typical oscillator frequency.



### 3.7 LOW-FREQUENCY OSCILLATOR

 $T_A = -40$  °C to 85 °C, 2.4 V <  $V_{CC}$  < 2.6 V; typical values at  $T_A = 25$  °C and  $V_{CC} = 2.5$  V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$f_{LOSC}$	Operating frequency			32.768		kHz
		$T_A = 0$ °C to 60°C	-1.5%	0.25%	1.5%	
f <sub>LEIO</sub>	Frequency error <sup>(1)</sup> (2)	$T_A = -20$ °C to 70°C	-2.5%	0.25%	2.5%	
		$T_A = -40$ °C to 85°C	-4%	0.25%	4%	
t <sub>LSXO</sub>	Start-up time <sup>(3)</sup>				500	μS

<sup>(1)</sup> The frequency drift is included and measured from the trimmed frequency at  $V_{CC} = 2.5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

### 3.8 INTEGRATING ADC (COULOMB COUNTER) CHARACTERISTICS

 $T_A = -40$ °C to 85°C, 2.4 V <  $V_{CC}$  < 2.6 V; typical values at  $T_A = 25$ °C and  $V_{CC} = 2.5$  V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{SR}$	Input voltage range, $V_{(SRN)}$ and $V_{(SRP)}$	$V_{SR} = V_{(SRN)} - V_{(SRP)}$	-0.125		0.125	V
t <sub>SR_CONV</sub>	Conversion time	Single conversion		1		S
	Resolution		14		15	bits
V <sub>OS(SR)</sub>	Input offset			10		μV
INL	Integral nonlinearity error			±0.007	±0.034	% FSR
Z <sub>IN(SR)</sub>	Effective input resistance (1)		2.5			ΜΩ
I <sub>lkg(SR)</sub>	Input leakage current <sup>(1)</sup>				0.3	μΑ

<sup>(1)</sup> Specified by design. Not tested in production.

### 3.9 ADC (TEMPERATURE AND CELL MEASUREMENT) CHARACTERISTICS

 $T_A = -40$ °C to 85°C, 2.4 V <  $V_{CC}$  < 2.6 V; typical values at  $T_A = 25$ °C and  $V_{CC} = 2.5$  V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>IN(ADC)</sub>	Input voltage range		0.05		1	V
t <sub>ADC_CONV</sub>	Conversion time				125	ms
	Resolution		14		15	bits
V <sub>OS(ADC)</sub>	Input offset			1		mV
Z <sub>ADC1</sub>	Effective input resistance (TS) <sup>(1)</sup>		8			ΜΩ
7	Effective input resistance (BAT) <sup>(1)</sup>	bq27520-G1 not measuring cell voltage	8			ΜΩ
Z <sub>ADC2</sub>	Effective input resistance (BAT)	bq27520-G1 measuring cell voltage		100		kΩ
I <sub>lkg(ADC)</sub>	Input leakage current <sup>(1)</sup>				0.3	μΑ

<sup>(1)</sup> Specified by design. Not tested in production.

<sup>(2)</sup> The frequency error is measured from 32.768 kHz.

<sup>(3)</sup> The start-up time is defined as the time it takes for the oscillator output frequency to be within ±3% of typical oscillator frequency.



### 3.10 DATA FLASH MEMORY CHARACTERISTICS

 $T_A = -40$ °C to 85°C, 2.4 V <  $V_{CC}$  < 2.6 V; typical values at  $T_A = 25$ °C and  $V_{CC} = 2.5$  V (unless otherwise noted)

, · ·	, , , , , , , , , , , , , , , , , , , ,	,,			,	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>DR</sub>	Data retention (1)		10			Years
	Flash-programming write cycles <sup>(1)</sup>		20,000			Cycles
t <sub>WORDPROG</sub>	Word programming time <sup>(1)</sup>				2	ms
I <sub>CCPROG</sub>	Flash-write supply current <sup>(1)</sup>			5	10	mA
t <sub>DFERASE</sub>	Data flash master erase time <sup>(1)</sup>		200			ms
t <sub>IFERASE</sub>	Instruction flash master erase time <sup>(1)</sup>		200			ms
t <sub>PGERASE</sub>	Flash page erase time <sup>(1)</sup>		20			ms

<sup>(1)</sup> Specified by design. Not production tested

### 3.11 I<sup>2</sup>C-COMPATIBLE INTERFACE COMMUNICATION TIMING CHARACTERISTICS

 $T_A = -40$ °C to 85°C, 2.4 V <  $V_{CC}$  < 2.6 V; typical values at  $T_A = 25$ °C and  $V_{CC} = 2.5$  V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP M	٩X	UNIT
t <sub>r</sub>	SCL/SDA rise time			3	00	ns
t <sub>f</sub>	SCL/SDA fall time			3	00	ns
t <sub>w(H)</sub>	SCL pulse duration (high)		600			ns
t <sub>w(L)</sub>	SCL pulse duration (low)		1.3			μS
t <sub>su(STA)</sub>	Setup for repeated start		600			ns
t <sub>d(STA)</sub>	Start to first falling edge of SCL		600			ns
t <sub>su(DAT)</sub>	Data setup time		100			ns
t <sub>h(DAT)</sub>	Data hold time		0			ns
t <sub>su(STOP)</sub>	Setup time for stop		600			ns
t <sub>(BUF)</sub>	Bus free time between stop and start		66			μS
f <sub>SCL</sub>	Clock frequency			4	00	kHz

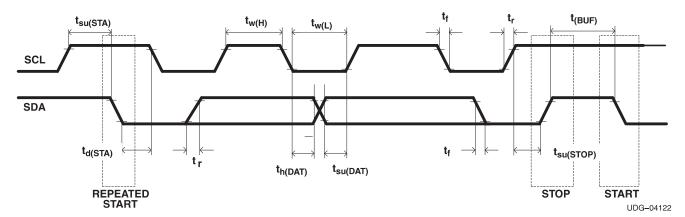


Figure 3-1. I<sup>2</sup>C-Compatible Interface Timing Diagrams

**ISTRUMENTS** 



SLUS<u>955-JUNE 2010</u>

### GENERAL DESCRIPTION

The bq27520-G1 accurately predicts the battery capacity and other operational characteristics of a single Li-based rechargeable cell. It can be interrogated by a system processor to provide cell information, such as time-to-empty (TTE), time-to-full (TTF) and state-of-charge (SOC) as well as SOC interrupt signal to the

Information is accessed through a series of commands, called Standard Commands, Further capabilities are provided by the additional Extended Commands set. Both sets of commands, indicated by the general format Command(), are used to read and write information contained within the device control and status registers, as well as its data flash locations. Commands are sent from system to gauge using the bq27520-G1's I<sup>2</sup>C serial communications engine, and can be executed during application development, pack manufacture, or end-equipment operation.

Cell information is stored in the device in non-volatile flash memory. Many of these data flash locations are accessible during application development. They cannot, generally, be accessed directly during end-equipment operation. Access to these locations is achieved by either use of the bq27520-G1's companion evaluation software, through individual commands, or through a sequence of data-flash-access commands. To access a desired data flash location, the correct data flash subclass and offset must be known.

The bq27520-G1 provides two 32-byte user-programmable data flash memory blocks: *Manufacturer Info* Block A and Manufacturer Info Block B. This data space is accessed through a data flash interface. For specifics on accessing the data flash, MANUFACTURER INFORMATION BLOCKS.

The key to the bg27520-G1's high-accuracy gas gauging prediction is Texas Instrument's proprietary Impedance Track™ algorithm. This algorithm uses cell measurements, characteristics, and properties to create state-of-charge predictions that can achieve less than 1% error across a wide variety of operating conditions and over the lifetime of the battery.

The device measures charge/discharge activity by monitoring the voltage across a small-value series sense resistor (5 m $\Omega$  to 20 m $\Omega$  typ.) located between the system's Vss and the battery's PACK- terminal. When a cell is attached to the device, cell impedance is computed, based on cell current, cell open-circuit voltage (OCV), and cell voltage under loading conditions.

The device external temperature sensing is optimized with the use of a high accuracy negative temperature coefficient (NTC) thermistor with R25 =  $10.0k\Omega \pm 1\%$ . B25/85 =  $3435K \pm 1\%$  (such as Semitec NTC 103AT). The bq27520-G1 can also be configured to use its internal temperature sensor. When an external themistor is used, a 18.2k pull up resistor between BT/TOUT and TS pins is also required. The bq27520-G1 uses temperature to monitor the battery-pack environment, which is used for fuel gauging and cell protection functionality.

To minimize power consumption, the device has different power modes: NORMAL, SLEEP, SLEEP+, HIBERNATE, and BAT INSERT CHECK. The bq27520-G1 passes automatically between these modes, depending upon the occurrence of specific events, though a system processor can initiate some of these modes directly. More details can be found in POWER MODES.

#### NOTE

#### FORMATTING CONVENTIONS IN THIS DOCUMENT:

Commands: italics with parentheses and no breaking spaces, e.g., RemainingCapacity()

Data flash: italics, bold, and breaking spaces, e.g., Design Capacity

Register bits and flags: brackets and italics, e.g., [TDA] Data flash bits: brackets, italics and bold, e.g., [LED1]

Modes and states: ALL CAPITALS, e.g., UNSEALED mode.

#### 4.1 DATA COMMANDS

### 4.1.1 STANDARD DATA COMMANDS

The bq27520-G1 uses a series of 2-byte standard commands to enable system reading and writing of battery information. Each standard command has an associated command-code pair, as indicated in Table 4-1. Because each command consists of two bytes of data, two consecutive I<sup>2</sup>C transmissions must be executed both to initiate the command function, and to read or write the corresponding two bytes of data. Additional options for transferring data, such as spooling, are described in Section of *Communication*. Standard commands are accessible in NORMAL operation. Read/Write permissions depend on the active access mode, SEALED or UNSEALED (for details on the SEALED and UNSEALED states, refer to Section 4.4, Access Modes.)

**Table 4-1. Standard Commands** 

NAME		COMMAND CODE	UNITS	SEALED ACCESS	UNSEALED ACCESS
Control()	CNTL	0x00 / 0x01	N/A	R/W	R/W
AtRate()	AR	0x02 / 0x03	mA	R/W	R/W
AtRateTimeToEmpty()	ARTTE	0x04 / 0x05	Minutes	R	R/W
Temperature()	TEMP	0x06 / 0x07	0.1 K	R/W	R/W
Voltage()	VOLT	0x08 / 0x09	mV	R	R/W
Flags()	FLAGS	0x0a / 0x0b	N/A	R	R/W
NominalAvailableCapacity()	NAC	0x0c / 0x0d	mAh	R	R/W
FullAvailableCapacity()	FAC	0x0e / 0x0f	mAh	R	R/W
RemainingCapacity()	RM	0x10 / 0x11	mAh	R	R/W
FullChargeCapacity()	FCC	0x12 / 0x13	mAh	R	R/W
AverageCurrent()	Al	0x14 / 0x15	mA	R	R/W
TimeToEmpty()	TTE	0x16 / 0x17	Minutes	R	R/W
TimeToFull()	TTF	0x18 / 0x19	Minutes	R	R/W
StandbyCurrent()	SI	0x1a / 0x1b	mA	R	R/W
StandbyTimeToEmpty()	STTE	0x1c / 0x1d	Minutes	R	R/W
MaxLoadCurrent()	MLI	0x1e / 0x1f	mA	R	R/W
MaxLoadTimeToEmpty()	MLTTE	0x20 / 0x21	Minutes	R	R/W
AvailableEnergy()	AE	0x22 / 0x23	mWh	R	R/W
AveragePower()	AP	0x24 / 0x25	mW	R	R/W
TTEatConstantPower()	TTECP	0x26 / 0x27	Minutes	R	R/W
StateOfHealth()	SOH	0x28 / 0x29	% / num	R	R/W
StateOfCharge()	SOC	0x2c / 0x2d	%	R	R/W
NormalizedImpedanceCal( )	NIC	0x2e / 0x2f	mohm	R	R/W
InstaneousCurrent Reading()	ICR	0x30 / 0x31	mA	R	R/W
DataLogindex( )	DLI	0x32 / 0x33	N/A	R	R
DataLogBuffer( )	DLB	0x34 / 0x35	mA	R	R



## 4.1.1.1 Control(): 0x00/0x01

Issuing a *Control()* command requires a subsequent 2-byte subcommand. These additional bytes specify the particular control function desired. The *Control()* command allows the system to control specific features of the bq27520-G1 during normal operation and additional features when the device is in different access modes, as described in Table 4-2.

Table 4-2. Control() Subcommands

CNTL FUNCTION	CNTL DATA	SEALED ACCESS	DESCRIPTION
CONTROL_STATUS	0x0000	Yes	Reports the status of DF checksum, hibernate, IT, etc.
DEVICE_TYPE	0x0001	Yes	Reports the device type (eg: bq27520-G1)
FW_VERSION	0x0002	Yes	Reports the firmware version on the device type
HW_VERSION	0x0003	Yes	Reports the hardware version of the device type
DF_CHECKSUM	0x0004	No	Enables a data flash checksum to be generated and reports on a read
PREV_MACWRITE	0x0007	Yes	Returns previous MAC subcommand code
CHEM_ID	0x0008	Yes	Reports the chemical identifier of the Impedance Track™ configuration
BOARD_OFFSET	0x0009	No	Forces the device to measure and store the board offset
CC_INT_OFFSET	0x000a	No	Forces the device to measure the internal CC offset
WRITE_CC_OFFSET	0x000b	No	Forces the device to store the internal CC offset
OCV_CMD	0x000c	Yes	Request the gauge to take a OCV measurement
BAT_INSERT	0x000d	Yes	Forces the BAT_DET bit set when the [BIE] bit is 0
BAT_REMOVE	0x000e	Yes	Forces the BAT_DET bit clear when the [BIE] bit is 0
SET_HIBERNATE	0x0011	Yes	Forces CONTROL_STATUS [HIBERNATE] to 1
CLEAR_HIBERNATE	0x0012	Yes	Forces CONTROL_STATUS [HIBERNATE] to 0
SET_SLEEP+	0x0013	Yes	Forces CONTROL_STATUS [SNOOZE] to 1
CLEAR_SLEEP+	0x0014	Yes	Forces CONTROL_STATUS [SNOOZE] to 0
FACTORY_RESTORE	0x0015	No	Forces a Factory Restore of learned resistance and Qmax to defaults
ENABLE_DLOG	0x0018	Yes	Commands the device to start coulomb counter Data Logging Mode.
DISABLE_DLOG	0x0019	Yes	Commands the device to stop Data Logging Mode.
SEALED	0x0020	No	Places the bq27520-G1 in SEALED access mode
IT_ENABLE	0x0021	No	Enables the Impedance Track™ algorithm
IT_DISABLE	0x0023	No	Disables the Impedance Track™ algorithm
CAL_MODE	0x0040	No	Places the bq27520-G1 in calibration mode
RESET	0x0041	No	Forces a full reset of the bq27520-G1

### TEXAS INSTRUMENTS

#### 4.1.1.1.1 CONTROL STATUS: 0x0000

Instructs the fuel gauge to return status information to control addresses 0x00/0x01. The status word includes the following information.

### Table 4-3. CONTROL\_STATUS Bit Definitions

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
High byte	DLOGEN	FAS	SS	CSV	CCA	BCA	OCVCMDCOMP	OCVFAIL
Low byte	INITCOMP	HIBERNATE	SNOOZE	SLEEP	LDMD	RUP_DIS	VOK	QEN

DLOGEN = Status biting the bq27520-G1 is in current Data Logging Mode. True when set.

FAS = Status bit indicating the bg27520-G1 is in FULL ACCESS SEALED state. Active when set.

SS = Status bit indicating the bq27520-G1 is in SEALED state. Active when set.

CSV = Status bit indicating a valid data flash checksum has been generated. Active when set.

CCA = Status bit indicating the bq27520-G1 Coulomb Counter Calibration routine is active. The CCA routine will take place approximately 1 minute after the initialization. Active when set.

BCA = Status bit indicating the bg27520-G1 board calibration routine is active. Active when set.

OCVCMDCOMP = Status bit indicating the bq27520-G1 has executed the OCV command. This bit can only be set with battery's presence. True when set

OCVFAIL = Status bit indicating bq27520-G1 OCV reading is failed due to the current. This bit can only be set with battery's presence. True when set.

INITCOMP = Initialization completion bit indicating the initialization completed. This bit can only be set with battery's presence. True when set

HIBERNATE = Status bit indicating a request for entry into HIBERNATE from SLEEP mode. True when set. Default is 0.

SNOOZE = Status bit indicating the bq27520-G1 SLEEP+ mode is enabled. True when set.

SLEEP = Status bit indicating the bq27520-G1 is in SLEEP mode. True when set.

LDMD = Status bit indicating the bq27520-G1 Impedance Track™ algorithm is using constant-power mode. True when set. Default is 0 (constant-current mode).

RUP\_DIS = Status bit indicating the bq27520-G1 Ra table updates are disabled. Updates disabled when set.

VOK = Status bit indicating the bg27520-G1 voltages are okay for Qmax. True when set.

QEN = Status bit indicating the bg27520-G1 Qmax updates enabled. True when set.

### 4.1.1.1.2 DEVICE\_TYPE: 0x0001

Instructs the fuel gauge to return the device type to addresses 0x00/0x01.

#### 4.1.1.1.3 FW VERSION: 0x0002

Instructs the fuel gauge to return the firmware version to addresses 0x00/0x01.

### 4.1.1.1.4 HW\_VERSION: 0x0003

Instructs the fuel gauge to return the hardware version to addresses 0x00/0x01.

### 4.1.1.1.5 DF\_CHECKSUM: 0x0004

Instructs the fuel gauge to compute the checksum of the data flash memory. The checksum value is written and returned to addresses 0x00/0x01 (UNSEALED mode only). The checksum will not be calculated in SEALED mode; however, the checksum value can still be read.

#### 4.1.1.1.6 PREV MACWRITE: 0x0007

Instructs the fuel gauge to return the previous subcommand written to addresses 0x00/0x01.

#### 4.1.1.1.7 CHEM ID: 0x0008

Instructs the fuel gauge to return the chemical identifier for the Impedance Track™ configuration to addresses 0x00/0x01.

### 4.1.1.1.8 BOARD\_OFFSET: 0X0009

Instructs the fuel gauge to compute the coulomb counter offset with internal short and then without internal short applied across the sensing resistor (SR) inputs. The difference between the two measurements is



the board offset. After a delay of approximately 32 seconds, this offset value is returned to addresses 0x00/0x01 and written to data flash. The CONTROL STATUS [BCA] is also set. The user must prevent any charge or discharge current from flowing during the process. This function is only available when the fuel gauge is UNSEALED. When SEALED, this command only reads back the board-offset value stored in data flash.

#### 4.1.1.1.9 CC INT OFFSET: 0X000A

Control data of 0x000a instructs the fuel gauge to compute the coulomb counter offset with internal short applied across the SR inputs. The offset value is returned to addresses 0x00/0x01, after a delay of approximately 16 seconds. This function is only available when the fuel gauge is UNSEALED. When SEALED, this command only reads back the CC\_INT\_OFFSET value stored in data flash.

### 4.1.1.1.10 WRITE\_OFFSET: 0X000B

Control data of 0x000b causes the fuel gauge to write the coulomb counter offset to data flash.

### 4.1.1.1.11 OCV CMD: 0X000C

This command is to request the gauge to take a OCV reading. This command can only be issued after the *[INICOMP]* has been set, indicating the initialization has been completed. The OCV measurement take place at the beginning of the next repeated 1s firmware synchronization clock. During the same time period, the SOC\_INT will pulse. The host should use this signal to reduce the load current below the C/20 in 8ms for a valid OCV reading. The OCV command *[OCVFAIL]* bit will be set if the OCV\_CMD is issued when *[CHG\_INH]* is set.

### 4.1.1.1.12 BAT INSERT: 0X000D

This command is to force the BAT\_DET bit to be set when the battery insertion detection is disabled. When the BIE is set to 0, the battery insertion detection is disabled. The gauge relies on the host to inform the battery insertion with this command to set the BAT\_DET bit.

#### 4.1.1.1.13 BAT REMOVE: 0X000E

This command is to force the BAT\_DET bit to be clear when the battery insertion detection is disabled. When the BIE is set to 0, the battery insertion detection is disabled. The gauge relies on the host to inform the battery removal with this command to clear the BAT\_DET bit.

### 4.1.1.1.14 SET\_HIBERNATE: 0x0011

Instructs the fuel gauge to force the CONTROL\_STATUS [HIBERNATE] bit to 1. This will allow the gauge to enter the HIBERNATE power mode after the transition to SLEEP power state is detected. The [HIBERNATE] bit is automatically cleared upon exiting from HIBERNATE mode.

### 4.1.1.1.15 CLEAR HIBERNATE: 0x0012

Instructs the fuel gauge to force the CONTROL\_STATUS [HIBERNATE] bit to 0. This prevents the gauge from entering the HIBERNATE power mode after the transition to the SLEEP power state is detected. It can also be used to force the gauge out of HIBERNATE mode.

### 4.1.1.1.16 ENABLE SLEEP+ MODE: 0X0013

Instructs the fuel gauge to set the CONTROL\_STATUS [SNOOZE] bit to 1. This will enable the SLEEP+ mode. The gauge will enter SLEEP+ power mode after the transition conditions are meet.

### 4.1.1.1.17 DISABLE SLEEP+ MODE: 0X0014

Instructs the fuel gauge to set the CONTROL\_STATUS [SNOOZE] bit to 0. This will disable the SLEEP+ mode. The gauge will exit from the SLEEP+ power mode after the SNOOZE bit is cleared.



#### 4.1.1.1.18 FACTORY RESTORE: 0X0015

Instructs the fuel gauge to reset learned resistance tables and Qmax values to the default values. SOC\_INT is asserted while the restore is in progress. This command is only available when the fuel gauge is UNSEALED.

### 4.1.1.1.19 ENABLE DLOG: 0x0018

Commands the fuel gauge to set the CONTROL\_STATUS[DLOGEN] bit to 1, clear the data FIFO, and begin recording coulomb counter data logging. While in Data Logging Mode, the device will not enter Sleep mode.

### 4.1.1.1.20 DISABLE DLOG: 0x0019

Commands the fuel gauge to clear the CONTROL\_STATUS[DLOGEN] bit to 0 and stop recording coulomb counter data. The previous data stored in the FIFO is not cleared.

### 4.1.1.1.21 SEALED: 0x0020

Instructs the fuel gauge to transition from the UNSEALED state to the SEALED state. The fuel gauge must always be set to the SEALED state for use in end equipment.

### 4.1.1.1.22 IT ENABLE: 0x0021

This command forces the fuel gauge to begin the Impedance Track<sup>TM</sup> algorithm, sets the *IT Enable* to 0x01 and causes the *[VOK]* and *[QEN]* flags to be set in the CONTROL\_STATUS register. *[VOK]* is cleared if the voltages are not suitable for a Qmax update. This command is only available when the fuel gauge is UNSEALED.

### 4.1.1.1.23 IT DISABLE: 0x0023

This command disables the fuel gauge the Impedance Track™ algorithm, clears the *IT Enable* to 0x00 and causes the *[QEN]* flags to be cleared in the CONTROL\_STATUS register. This command is only available when the fuel gauge is UNSEALED.

### 4.1.1.1.24 CAL MODE: 0X0040

This command instructs the fuel gauge to enter calibration mode. This command is only available when the fuel gauge is UNSEALED.

#### 4.1.1.1.25 RESET: 0x0041

This command instructs the fuel gauge to perform a full reset. This command is only available when the fuel gauge is UNSEALED.

### 4.1.1.2 AtRate(): 0x02/0x03

The AtRate() read-/write-word function is the first half of a two-function command set used to set the AtRate value used in calculations made by the AtRateTimeToEmpty() function. The AtRate() units are in mA.

The AtRate() value is a signed integer, with negative values interpreted as a discharge current value. The AtRateTimeToEmpty() function returns the predicted operating time at the AtRate value of discharge. The default value for AtRate() is zero and forces AtRateTimeToEmpty() to return 65,535. Both the AtRate() and AtRateTimeToEmpty() commands must only be used in NORMAL mode.

### 4.1.1.3 AtRateTimeToEmpty(): 0x04/0x05

This read-word function returns an unsigned integer value of the predicted remaining operating time if the



battery is discharged at the AtRate() value in minutes with a range of 0 to 65,534. A value of 65,535 indicates AtRate() = 0. The fuel gauge updates AtRateTimeToEmpty() within 1 s after the system sets the AtRate() value. The fuel gauge automatically updates AtRateTimeToEmpty() based on the AtRate() value every 1 s. Both the AtRate() and AtRateTimeToEmpty() commands must only be used in NORMAL mode.

### 4.1.1.4 Temperature(): 0x06/0x07

This read-/write-word function returns an unsigned integer value of the temperature in units of 0.1 K measured by the fuel gauge. If [WRTEMP] bit = 1, a write command sets the temperature to be used for gauging calculations while a read command returns to temperature previously written. If [WRTEMP] bit = 0 and [TEMPS] bit = 0, a read command will return the internal temperature sensor value.

### 4.1.1.5 *Voltage()*: 0x08/0x09

This read-word function returns an unsigned integer value of the measured cell-pack voltage in mV with a range of 0 to 6000 mV.

### 4.1.1.6 Flags(): 0x0a/0x0b

This read-word function returns the contents of the fuel-gauge status register, depicting the current operating status.

**Table 4-4. Flags Bit Definitions** 

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
High byte	OTC	OTD	_	_	CHG_INH	XCHG	FC	CHG
Low byte	_	_	OCV_GD	WAIT_ID	BAT_DET	SOC1	SYSDOWN	DSG

OTC = Overtemperature in charge condition is detected. True when set.

CHG\_INH = Charge inhibit: unable to begin charging (temperature outside the range [Charge Inhibit Temp Low, Charge Inhibit Temp High]). True when set.

XCHG = Charge suspend alert (temperature outside the range [Suspend Temperature Low, Suspend Temperature High]). True when set.

FC = Full-charged condition reached. Set when charge termination condition is met. (RMFCC=1; Set FC\_Set % = -1% when RMFCC = 0). True when set

CHG = (Fast) charging allowed. True when set.

OCV\_GD = Good OCV measurement taken. True when set.

WAIT\_ID = Waiting to identify inserted battery. True when set.

BAT\_DET = Battery detected. True when set.

SOC1 = State-of-charge threshold 1 (SOC1 Set) reached. The flag is enabled when BL\_INT bit in Operation Configuration B is set. True when set.

SysDown = SystemDown bit indicating the system shut down. True when set

DSG = Discharging detected. True when set.

### 4.1.1.7 NominalAvailableCapacity(): 0x0c/0x0d

This read-only command pair returns the uncompensated (less than C/20 load) battery capacity remaining. Units are mAh.

### 4.1.1.8 FullAvailableCapacity(): 0x0e/0x0f

This read-only command pair returns the uncompensated (less than C/20 load) capacity of the battery when fully charged. Units are mAh. *FullAvailableCapacity()* is updated at regular intervals, as specified by the IT algorithm.

### 4.1.1.9 RemainingCapacity(): 0x10/0x11

This read-only command pair returns the compensated battery capacity remaining. Units are mAh.

#### 4.1.1.10 FullChargeCapacity(): 0x12/13

This read-only command pair returns the compensated capacity of the battery when fully charged. Units are mAh. *FullChargeCapacity()* is updated at regular intervals, as specified by the IT algorithm.

OTD = Overtemperature in discharge condition is detected. True when set.



### 4.1.1.11 AverageCurrent(): 0x14/0x15

This read-only command pair returns a signed integer value that is the average current flow through the sense resistor. It is updated every 1 second. Units are mA.

### 4.1.1.12 *TimeToEmpty()*: 0x16/0x17

This read-only function returns an unsigned integer value of the predicted remaining battery life at the present rate of discharge, in minutes. A value of 65,535 indicates battery is not being discharged.

### 4.1.1.13 TimeToFull(): 0x18/0x19

This read-only function returns an unsigned integer value of predicted remaining time until the battery reaches full charge, in minutes, based upon *AverageCurrent()*. The computation accounts for the taper current time extension from the linear TTF computation based on a fixed *AverageCurrent()* rate of charge accumulation. A value of 65,535 indicates the battery is not being charged.

### 4.1.1.14 StandbyCurrent(): 0x1a/0x1b

This read-only function returns a signed integer value of the measured standby current through the sense resistor. The *StandbyCurrent()* is an adaptive measurement. Initially it reports the standby current programmed in *Initial Standby*, and after spending several seconds in standby, reports the measured standby current.

The register value is updated every 1 second when the measured current is above the **Deadband** and is less than or equal to 2 x **Initial Standby**. The first and last values that meet this criteria are not averaged in, since they may not be stable values. To approximate a 1 minute time constant, each new **StandbyCurrent()** value is computed by taking approximate 93% weight of the last standby current and approximate 7% of the current measured average current.

### 4.1.1.15 StandbyTimeToEmpty(): 0x1c/0x1d

This read-only function returns an unsigned integer value of the predicted remaining battery life at the standby rate of discharge, in minutes. The computation uses *Nominal Available Capacity* (NAC), the uncompensated remaining capacity, for this computation. A value of 65,535 indicates battery is not being discharged.

### 4.1.1.16 MaxLoadCurrent(): 0x1e/0x1f

This read-only function returns a signed integer value, in units of mA, of the maximum load conditions. The MaxLoadCurrent() is an adaptive measurement which is initially reported as the maximum load current programmed in Initial Max Load Current. If the measured current is ever greater than Initial Max Load Current, then MaxLoadCurrent() updates to the new current. MaxLoadCurrent() is reduced to the average of the previous value and Initial Max Load Current whenever the battery is charged to full after a previous discharge to an SOC less than 50%. This prevents the reported value from maintaining an unusually high value.

#### 

This read-only function returns an unsigned integer value of the predicted remaining battery life at the maximum load current discharge rate, in minutes. A value of 65,535 indicates that the battery is not being discharged.

### 

This read-only function returns an unsigned integer value of the predicted charge or energy remaining in the battery. The value is reported in units of mWh.



### 4.1.1.19 AveragePower(): 0x24/0x25

This read-only function returns an signed integer value of the average power during battery charging and discharging. It is negative during discharge and positive during charge. A value of 0 indicates that the battery is not being discharged. The value is reported in units of mW.

### 4.1.1.20 TimeToEmptyAtConstantPower(): 0x26/0x27

This read-only function returns an unsigned integer value of the predicted remaining operating time if the battery is discharged at the *AveragePower()* value in minutes. A value of 65,535 indicates *AveragePower()* = 0. The fuel gauge automatically updates *TimeToEmptyatContantPower()* based on the *AveragePower()* value every 1 s.

### 4.1.1.21 StateofHealth(): 0x28/0x29

0x28 SOH percentage: this read-only function returns an unsigned integer value, expressed as a percentage of the ration of predicted *FCC(25°C, SOH LoadI)* over the *DesignCapacity()*. The *FCC(25°C, SOH LoadI)* is the calculated full charge capacity at 25°C and the *SOH LoadI* which is specified in the data flash. The range of the returned SOH percentage is 0x00 to 0x64, indicating 0 to 100% correspondingly.

0x29 SOH Status: this read-only function returns an unsigned integer value, indicating the status of the SOH percentage. The meanings of the returned value are:

- 0x00: SOH not valid (initialization)
- 0x01: Instant SOH value ready
- 0x02: Initial SOH value ready
  - Calculation based on uncompensated Qmax
  - Updated at first grid point update after cell insertion
- 0x03: SOH value ready
  - Utilize the updated Qmax update
  - Calculation based on compensated Qmax
  - Updated after complete charge and relax is complete
- 0x04-0xFF: Reserved

#### 4.1.1.22 StateOfCharge(): 0x2c/0x2d

This read-only function returns an unsigned integer value of the predicted remaining battery capacity expressed as a percentage of *FullChargeCapacity()*, with a range of 0 to 100%.

### 4.1.1.23 NormalizedImpedanceCal(): 0x2e/0x2f

This read-only function returns an unsigned integer value of the calculated normalized impedance to  $0^{\circ}$ C at the current Depth of Discharge, with the unit of m $\Omega$ .

#### 4.1.1.24 InstaneousCurrent Reading() 0x30/0x31

This read-only function returns a signed integer value that is the instantaneous current flow through the sense resistor. The conversion time is 125ms. It is updated every 1 second. Units are mA.

### 4.1.1.25 DataLogIndex(): 0x32/0x33

In Data Logging Mode, this read-only register returns an unsigned integrer that increments for every new coulomb counter sample placed in the data FIFO and decrements for each sample read by the host from DataLogBuffer(). The index saturates at 30 counts to prevent rollover of the FIFO and subsequent data samples are discarded. Data logging is controlled by the ENABLE\_DLOG and DISABLE\_DLOG subcommands while status is provided by the CONTROL\_STATUS[DLOGEN] bit.



### 4.1.1.26 DataLogBuffer(): 0x34/0x35

In Data Logging Mode, this read-only register returns a 16-bit signed coulomb counter value in mA. Access to data is provided by a 30 sample FIFO with the number of samples available from DataLogIndex(). If the FIFO is empty, this value returned is 0x7FFF.

### 4.1.2 EXTENDED DATA COMMANDS

Extended commands offer additional functionality beyond the standard set of commands. They are used in the same manner; however, unlike standard commands, extended commands are not limited to 2-byte words. The number of commands bytes for a given extended command ranges in size from single to multiple bytes, as specified in Table 4-5.

**Table 4-5. Extended Data Commands** 

NAME		COMMAND CODE	UNITS	SEALED ACCESS <sup>(1)</sup> (2)	UNSEALED ACCESS <sup>(1)</sup> (2)
Reserved	RSVD	0x340x3b	N/A	R	R
DesignCapacity()	DCAP	0x3c / 0x3d	mAh	R	R
DataFlashClass() (2)	DFCLS	0x3e	N/A	N/A	R/W
DataFlashBlock() (2)	DFBLK	0x3f	N/A	R/W	R/W
BlockData()	DFD	0x400x5f	N/A	R	R/W
BlockDataCheckSum()	DFDCKS	0x60	N/A	R/W	R/W
BlockDataControl()	DFDCNTL	0x61	N/A	N/A	R/W
DeviceNameLength()	DNAMELEN	0x62	N/A	R	R
DeviceName()	DNAME	0x630x69	N/A	R	R
ApplicationStatus( )	APPSTAT	0x6a	N/A	R	R
Reserved	RSVD	0x6b0x7f	N/A	R	R

<sup>(1)</sup> SEALED and UNSEALED states are entered via commands to *Control()* 0x00/0x01.

### 4.1.2.1 DesignCapacity(): 0x3c/0x3d

**SEALED and UNSEALED Access:** This command returns the value is stored in *Design Capacity* and is expressed in mAh. This is intended to be the theoretical or nominal capacity of a new pack, but has no bearing on the operation of the fuel gauge functionality.

### 4.1.2.2 DataFlashClass(): 0x3e

**UNSEALED Access:** This command sets the data flash class to be accessed. The class to be accessed must be entered in hexadecimal.

**SEALED Access:** This command is not available in SEALED mode.

<sup>(2)</sup> In sealed mode, data flash CANNOT be accessed through commands 0x3e and 0x3f.



### 4.1.2.3 DataFlashBlock(): 0x3f

**UNSEALED Access:** This command sets the data flash block to be accessed. When 0x00 is written to *BlockDataControl()*, *DataFlashBlock()* holds the block number of the data flash to be read or written. Example: writing a 0x00 to *DataFlashBlock()* specifies access to the first 32-byte block, a 0x01 specifies access to the second 32-byte block, and so on.

**SEALED Access:** This command directs which data flash block is accessed by the *BlockData()* command. Writing a 0x01 or 0x02 instructs the *BlockData()* command to transfer *Manufacturer Info Block A* or *B*, respectively. All other *DataFlashBlock()* values are reserved.

### 4.1.2.4 BlockData(): 0x40...0x5f

**UNSEALED Access:** This data block is the remainder of the 32 byte data block when accessing data flash.

**SEALED Access:** This data block is the remainder of the 32 byte data block when accessing *Manufacturer Block Info A or B*.

### 4.1.2.5 BlockDataChecksum(): 0x60

**UNSEALED Access:** This byte contains the checksum on the 32 bytes of block data read or written to data flash. The least-significant byte of the sum of the data bytes written must be complemented ([255 - x], for x the least-significant byte) before being written to 0x60.

**SEALED Access:** This byte contains the checksum for the 32 bytes of block data written to **Manufacturer Info Block A or B**. The least-significant byte of the sum of the data bytes written must be complemented ([255 - x], for x the least-significant byte) before being written to 0x60.

### 4.1.2.6 BlockDataControl(): 0x61

**UNSEALED Access:** This command is used to control data flash access mode. Writing 0x00 to this command enables *BlockData()* to access general data flash. Writing a 0x01 to this command enables SEALED mode operation of *DataFlashBlock()*.

SEALED Access: This command is not available in SEALED mode.

### 4.1.2.7 DeviceNameLength(): 0x62

UNSEALED and SEALED Access: This byte contains the length of the Device Name.

### 4.1.2.8 DeviceName(): 0x63...0x69

**UNSEALED and SEALED Access:** This block contains the device name that is programmed in *Device Name*.

### 4.1.2.9 ApplicationStatus(): 0x6a

This byte function allows the system to read the bq27520-G1 *Application Status* data flash location. See Table 6-1 for specific bit definitions.

#### 4.1.2.10 Reserved — 0x6b-0x7f



#### 4.2 DATA FLASH INTERFACE

### 4.2.1 ACCESSING THE DATA FLASH

The bq27520-G1 data flash is a non-volatile memory that contains bq27520-G1 initialization, default, cell status, calibration, configuration, and user information. The data flash can be accessed in several different ways, depending on what mode the bq27520-G1 is operating in and what data is being accessed.

Commonly accessed data flash memory locations, frequently read by a system, are conveniently accessed through specific instructions, already described in Section 4.1, DATA COMMANDS. These commands are available when the bq27520-G1 is either in UNSEALED or SEALED modes.

Most data flash locations, however, are only accessible in UNSEALED mode by use of the bq27520-G1 evaluation software or by data flash block transfers. These locations should be optimized and/or fixed during the development and manufacture processes. They become part of a golden image file and can then be written to multiple battery packs. Once established, the values generally remain unchanged during end-equipment operation.

To access data flash locations individually, the block containing the desired data flash location(s) must be transferred to the command register locations, where they can be read to the system or changed directly. This is accomplished by sending the set-up command <code>BlockDataControl()</code> (0x61) with data 0x00. Up to 32 bytes of data can be read directly from the <code>BlockData()</code> (0x40...0x5f), externally altered, then rewritten to the <code>BlockData()</code> command space. Alternatively, specific locations can be read, altered, and rewritten if their corresponding offsets are used to index into the <code>BlockData()</code> command space. Finally, the data residing in the command space is transferred to data flash, once the correct checksum for the whole block is written to <code>BlockDataChecksum()</code> (0x60).

Occasionally, a data flash CLASS will be larger than the 32-byte block size. In this case, the DataFlashBlock() command is used to designate which 32-byte block the desired locations reside in. The correct command address is then given by 0x40 + offset modulo 32. For example, to access Terminate Voltage in the Gas Gauging class, DataFlashClass() is issued 80 (0x50) to set the class. Because the offset is 50, it must reside in the second 32-byte block. Hence, DataFlashBlock() is issued 0x01 to set the block offset, and the offset used to index into the BlockData() memory area is 0x40 + 50 modulo 32 = 0x40 + 18 = 0x40 + 0x12 = 0x52.

Reading and writing subclass data are block operations up to 32 bytes in length. If during a write the data length exceeds the maximum block size, then the data is ignored.

None of the data written to memory are bounded by the bq27520-G1 – the values are not rejected by the fuel gauge. Writing an incorrect value may result in hardware failure due to firmware program interpretation of the invalid data. The written data is persistent, so a power-on reset does resolve the fault.



#### 4.3 MANUFACTURER INFORMATION BLOCKS

The bq27520-G1 contains 96 bytes of user programmable data flash storage: **Manufacturer Info Block A**, and **Manufacturer Info Block B**. The method for accessing these memory locations is slightly different, depending on whether the device is in UNSEALED or SEALED modes.

When in UNSEALED mode and when and 0x00 has been written to <code>BlockDataControl()</code>, accessing the manufacturer information blocks is identical to accessing general data flash locations. First, a <code>DataFlashClass()</code> command is used to set the subclass, then a <code>DataFlashBlock()</code> command sets the offset for the first data flash address within the subclass. The <code>BlockData()</code> command codes contain the referenced data flash data. When writing the data flash, a checksum is expected to be received by <code>BlockDataChecksum()</code>. Only when the checksum is received and verified is the data actually written to data flash.

As an example, the data flash location for **Manufacturer Info Block B** is defined as having a Subclass = 58 and an Offset = 32 through 63 (32 byte block). The specification of Class = System Data is not needed to address **Manufacturer Info Block B**, but is used instead for grouping purposes when viewing data flash info in the bg27520-G1 evaluation software.

When in SEALED mode or when 0x01 *BlockDataControl()* does not contain 0x00, data flash is no longer available in the manner used in UNSEALED mode. Rather than issuing subclass information, a designated Manufacturer Information Block is selected with the *DataFlashBlock()* command. Issuing a 0x01 or 0x02 with this command causes the corresponding information block (A or B, respectively) to be transferred to the command space 0x40...0x5f for editing or reading by the system. Upon successful writing of checksum information to *BlockDataChecksum()*, the modified block is returned to data flash. *Note: Manufacturer Info Block A* is read-only when in SEALED mode.



#### 4.4 ACCESS MODES

The bq27520-G1 provides three security modes (FULL ACCESS, UNSEALED, and SEALED) that control data flash access permissions, according to Table 4-6. Data Flash refers to those data flash locations, specified in Table 4-7, that are accessible to the user. Manufacture Information refers to the three 32-byte blocks.

Table 4-6. Data Flash Access

Security Mode	Data Flash	Manufacture Information
FULL ACCESS	R/W	R/W
UNSEALED	R/W	R/W
SEALED	None	R(A); R/W(B)

Although FULL ACCESS and UNSEALED modes appear identical, only FULL ACCESS allows the bq27520-G1 to write access-mode transition keys.

### 4.5 SEALING/UNSEALING DATA FLASH

The bq27520-G1 implements a key-access scheme to transition between SEALED, UNSEALED, and FULL-ACCESS modes. Each transition requires that a unique set of two keys be sent to the bq27520-G1 via the *Control()* control command. The keys must be sent consecutively, with no other data being written to the *Control()* register in between. Note that to avoid conflict, the keys must be different from the codes presented in the *CNTL DATA* column of Table 4-2 subcommands.

When in SEALED mode, the CONTROL\_STATUS [SS] bit is set, but when the UNSEAL keys are correctly received by the bq27520-G1, the [SS] bit is cleared. When the full-access keys are correctly received, then the CONTROL\_STATUS [FAS] bit is cleared.

Both the sets of keys for each level are 2 bytes each in length and are stored in data flash. The UNSEAL key (stored at *Unseal Key 0* and *Unseal Key 1*) and the FULL-ACCESS key (stored at *Full-Access Key 0* and *Full-Access Key 1*) can only be updated when in FULL-ACCESS mode. The order of the keys is *Key 1* followed by *Key 0*. The order of the bytes entered through the *Control()* command is the reverse of what is read from the part. For example, if the *Key 1* and *Key* 0 of the *Unseal Keys* returns 0x1234 and 0x5678, then the *Control()* should supply 0x3412 and 0x7856 to unseal the part.



### 4.6 DATA FLASH SUMMARY

Table 4-7 summarizes the data flash locations available to the user, including their default, minimum, and maximum values.

**Table 4-7. Data Flash Summary** 

Configuration	2 2 2 2 2 2 2 32 32 32 32 34	Safety Safety Safety Safety Safety Safety Charge Inhibit Temp Low Charge Inhibit Temp High Temp Hysteresis	0 2 3 5 7 8 0 2	OT Chg OT Chg Time OT Chg Recovery OT Dsg OT Dsg Time OT Dsg Recovery  Charge Inhibit Temp Low Charge Inhibit Temp High	12	0 0 0 0 0 0 0 -400	1200 60 1200 1200 60 1200	550 2 500 600 2 550	0.1°C s 0.1°C 0.1°C s 0.1°C
Configuration Configuration Configuration Configuration Configuration Configuration Configuration Configuration	2 2 2 2 32 32 32 32 34	Safety Safety Safety Safety Charge Inhibit Temp Low Charge Inhibit Temp High Temp	3 5 7 8 0	OT Chg Recovery OT Dsg OT Dsg Time OT Dsg Recovery  Charge Inhibit Temp Low Charge Inhibit Temp High	12	0 0 0 0 -400	1200 1200 60 1200	500 600 2 550	0.1°C 0.1°C s 0.1°C
Configuration Configuration Configuration Configuration Configuration Configuration	2 2 2 32 32 32 32 34	Safety Safety Safety Charge Inhibit Temp Low Charge Inhibit Temp High Temp	5 7 8 0	OT Dsg OT Dsg Time OT Dsg Recovery  Charge Inhibit Temp Low Charge Inhibit Temp High	I2 U1 I2	0 0 0 -400	1200 60 1200	600 2 550	0.1°C s 0.1°C
Configuration Configuration Configuration Configuration Configuration	2 2 32 32 32 32 34	Safety Safety Charge Inhibit Temp Low Charge Inhibit Temp High Temp	7 8 0 2	OT Dsg Time OT Dsg Recovery  Charge Inhibit Temp Low  Charge Inhibit Temp High	U1 I2	0 0 -400	60 1200	2 550	s 0.1°C
Configuration  Configuration  Configuration  Configuration	2 32 32 32 32 34	Safety  Charge Inhibit Temp Low  Charge Inhibit Temp High  Temp	0 2	OT Dsg Recovery  Charge Inhibit Temp Low  Charge Inhibit Temp High	l2 l2	-400	1200	550	0.1°C
Configuration Configuration Configuration	32 32 32 32	Charge Inhibit Temp Low Charge Inhibit Temp High Temp	0 2	Charge Inhibit Temp Low  Charge Inhibit Temp High	12	-400			
Configuration  Configuration	32 32 34	Temp Low Charge Inhibit Temp High Temp	2	Charge Inhibit Temp High			1200	0	0.1°C
Configuration	32	Temp High Temp			12	-400			
	34		4	Tomp Hya			1200	450	0.1°C
Configuration				Temp Hys	12	0	100	50	0.1°C
	24	Charge	2	Charging Voltage	12	0	4600	4200	mV
Configuration	34	Charge	4	Delta Temp	12	0	500	50	0.1°C
Configuration	34	Charge	6	Suspend Low Temp	12	-400	1200	-50	0.1°C
Configuration	34	Charge	8	Suspend High Temp	12	-400	1200	550	0.1°C
Configuration	36	Charge Termination	2	Taper Current	12	0	1000	100	mA
Configuration	36	Charge Termination	4	Minimum Taper Charge	12	0	1000	25	0.01mAl
Configuration	36	Charge Termination	6	Taper Voltage	12	0	1000	100	mV
Configuration	36	Charge Termination	8	Current Taper Window	U1	0	60	40	s
Configuration	36	Charge Termination	11	FC Set %	I1	-1	100	100	%
Configuration	36	Charge Termination	12	FC Clear %	I1	-1	100	98	%
Configuration	48	Data	4	Initial Standby Current	I1	-128	0	-10	mA
Configuration	48	Data	5	Initial Max Load Current	12	-32,767	0	-500	mA
Configuration	48	Data	7	CC Threshold	12	100	32,767	900	mAh
Configuration	48	Data	10	Design Capacity	12	0	65,535	1000	mAh
Configuration	48	Data	12	SOH Load	12	-32,767	0	-400	mA
Configuration	48	Data	14	Default Temp	12	0	1000	250 <sup>(1)</sup>	0.1°C
Configuration	48	Data	16	Device name	S8	x	Х	bq27520- G1	-
Configuration	49	Discharge	0	SOC1 Set Threshold	U1	0	255	150	mAh
Configuration	49	Discharge	1	SOC1 Clear Threshold	U1	0	255	175	mAh
Configuration	49	Discharge	5	SysDown Set Volt Threshold	12	0	4200	3150	mV
Configuration	49	Discharge	7	SysDown Set Volt Time	U1	0	60	2	S
Configuration	49	Discharge	8	SysDown Clear Volt Threshold	12	0	4200	3400	mV
Configuration	49	Discharge	15	Final Voltage	U2	0	4200	3000	mV
Configuration	56	Integrity Data	1	Full Reset Counter	U1	0	255	0	num
System Data	57	Manufacturer Info	0	Block A 0	H1	0x00	0xff	0x00	-
System Data	57	Manufacturer Info	1–31	Block A [10-31]	H1	0x00	0xff	0x00	_



## Table 4-7. Data Flash Summary (continued)

	Table 4-7. Data Flash Summary (continued)											
Class	Subclass ID	Subclass	Offset	Name	Data Type	Min Value	Max Value	Default Value	Units			
System Data	57	Manufacturer Info	32–63	Block B [0-31]	H1	0x00	0xff	0x00	_			
Configuration	64	Registers	0	Operation Configuration	H2	0x0000	0xffff	0x0973	-			
Configuration	64	Registers	7	SOC Delta	U1	0	25	1	%			
Configuration	64	Registers	8	I <sup>2</sup> C Timeout	U1	0	7	4	num			
Configuration	64	Registers	9	DFWrIndWaitTime	U2	0	65535	0	5μs			
Configuration	64	Registers	11	OpConfigB	H1	0x00	0xff	0x50	-			
Configuration	68	Power	0	Flash Update OK Voltage	12	0	4200	2800	mV			
Configuration	68	Power	7	Sleep Current	12	0	100	10	mA			
Configuration	68	Power	16	Hibernate Current	U2	0	700	8	mA			
Configuration	68	Power	18	Hibernate Voltage	U2	2400	3000	2550	mV			
Configuration	68	Power	21	Max Res Factor	U1	0	255	20	num			
Configuration	68	Power	22	Min Res Factor	U1	0	255	5	num			
Gas Gauging	80	IT Cfg	0	Load Select	U1	0	255	1	_			
Gas Gauging	80	IT Cfg	1	Load Mode	U1	0	255	0	-			
Gas Gauging	80	IT Cfg	24	Ra Filter	U2	0	1000	800	num			
Gas Gauging	80	IT Cfg	40	Min % Passed Charge for Qmax	U1	1	100	37	%			
Gas Gauging	80	IT Cfg	44	Qmax Filter	U1	0	255	96	num			
Gas Gauging	80	IT Cfg	45	Terminate Voltage	12	-32,768	32,767	3420	mV			
Gas Gauging	80	IT Cfg	50	User Rate-mA	12	-2000	-100	0	mA			
Gas Gauging	80	IT Cfg	52	User Rate-mW	12	-7200	-350	0	mW			
Gas Gauging	80	IT Cfg	54	Reserve Cap-mAh	12	0	9000	0	mAh			
Gas Gauging	80	IT Cfg	56	Reserve Cap-mWh	12	0	14,000	0	mWh			
Gas Gauging	80	IT Cfg	61	Min Delta Voltage	12	-32,000	32,000	0	mV			
Gas Gauging	80	IT Cfg	63	Max Sim Rate	U1	0	255	2	C/rate			
Gas Gauging	80	IT Cfg	64	Min Sim Rate	U1	0	255	20	C/rate			
Gas Gauging	80	IT Cfg	65	Ra MAx Delta	U2	0	65,535	44	mΩ			
Gas Gauging	80	IT Cfg	67	Qmax MAx Delta%	U1	0	255	5	%			
Gas Gauging	80	IT Cfg	68	DeltaV Max dV	U2	0	65,535	10	mV			
Gas Gauging	81	Current Thresholds	0	Dsg Current Threshold	12	0	2000	60	mA			
Gas Gauging	81	Current Thresholds	2	Chg Current Threshold	12	0	2000	75	mA			
Gas Gauging	81	Current Thresholds	4	Quit Current	12	0	1000	40	mA			
Gas Gauging	81	Current Thresholds	6	Dsg Relax Time	U2	0	8191	60	s			
Gas Gauging	81	Current Thresholds	8	Chg Relax Time	U1	0	255	60	S			
Gas Gauging	81	Current Thresholds	9	Quit Relax Time	U1	0	63	1	S			
Gas Gauging	81	Current Thresholds	10	Transient Factor Charge	U1	0	255	255	num			
Gas Gauging	81	Current	11	Transient Factor Discharge	U1	0	255	255	num			
Gas Gauging	81	Thresholds Current Thresholds	12	Max IR Correct	U2	0	1,000	400	mV			
Gas Gauging	82	State	0	IT Enable	H1	0x00	0x03	0x00	_			
Gas Gauging Gas Gauging	82	State	1	Application Status	H1	0x00	0x03 0xff	0x00	_			
Gas Gauging Gas Gauging	82	State	2	Qmax 0	12	0	32,767	1000	mAh			
Jac Jauging									110 111			
Gas Gauging	82	State	4	Cycle Count 0	U2	0	65,535	0	_			



www.ti.com \_\_\_\_\_\_SLUS955-JUNE 2010

### Table 4-7. Data Flash Summary (continued)

Class	Subclass ID	Subclass	Offset	Name	Data Type	Min Value	Max Value	Default Value	Units
Gas Gauging	82	State	7	Qmax 1	12	0	32767	1000	mAh
Gas Gauging	82	State	9	Cycle Count 1	U2	0	65,535	0	Count
Gas Gauging	82	State	11	Update Status 1	H1	0x00	0x03	0x00	-
Gas Gauging	82	State	12	Cell0 Chg dod	12	0	16384	0	-
Gas Gauging	82	State	14	Cell1 Chg dod at EoC	12	0	16384	0	-
Gas Gauging	82	State	16	Avg I Last Run	12	-32,768	32,767	-299	mA
Gas Gauging	82	State	18	Avg P Last Run	12	-32,768	32,767	-1131	mAh
Gas Gauging	82	State	20	Delta Voltage	12	-32,768	32,768	2	mV
Calibration	104	Data	0	CC Gain	F4 <sup>(2)</sup>	0.1	47	10 <sup>(3)</sup>	mohm
Calibration	104	Data	4	CC Delta	F4 <sup>(2)</sup>	4.7	188	10 <sup>(3)</sup>	mohm
Calibration	104	Data	8	CC Offset	12	-2.4	2.4	-0.088 <sup>(3)</sup>	mV
Calibration	104	Data	10	ADC Offset	12	-500	500	0	mV
Calibration	104	Data	12	Board Offset	I1	-128	127	0	mV
Calibration	104	Data	13	Int Temp Offset	I1	-128	127	0	0.1°C
Calibration	104	Data	14	Ext Temp Offset	I1	-128	127	0	0.1°C
Calibration	104	Data	15	Pack V Offset	I1	-128	127	0	mV
Calibration	107	Current	1	Deadband	U1	0	255	5	mA
Security	112	Codes	0	Unseal Key 0	H2	0x0000	0xffff	0x3672	-
Security	112	Codes	2	Unseal Key 1	H2	0x0000	0xffff	0x0414	_
Security	112	Codes	4	Unsealed to Full 0	H2	0x0000	0xffff	0xffff	-
Security	112	Codes	6	Unsealed to Full 1	H2	0x0000	0xffff	0xffff	-
Security	112	Codes	24	FactRestorkey 0	H2	0x0000	0xffff	0x0DEF	-
Security	112	Codes	26	FactRestorkey 1	H2	0x0000	0xffff	0x0FAC	-

<sup>(2)</sup> Not IEEE floating point.

### 5 FUNCTIONAL DESCRIPTION

### 5.1 FUEL GAUGING

The bq27520-G1 measures the cell voltage, temperature, and current to determine battery SOC. The bq27520-G1 monitors charge and discharge activity by sensing the voltage across a small-value resistor (5 m $\Omega$  to 20 m $\Omega$  typ.) between the SRP and SRN pins and in series with the cell. By integrating charge passing through the battery, the battery's SOC is adjusted during battery charge or discharge.

The total battery capacity is found by comparing states of charge before and after applying the load with the amount of charge passed. When an application load is applied, the impedance of the cell is measured by comparing the OCV obtained from a predefined function for present SOC with the measured voltage under load. Measurements of OCV and charge integration determine chemical state of charge and chemical capacity (Qmax). The initial Qmax values are taken from a cell manufacturers' data sheet multiplied by the number of parallel cells. It is also used for the value in **Design Capacity**. The bq27520-G1 acquires and updates the battery-impedance profile during normal battery usage. It uses this profile, along with SOC and the Qmax value, to determine FullChargeCapacity() and StateOfCharge(), specifically for the present load and temperature. FullChargeCapacity() is reported as capacity available from a fully charged battery under the present load and temperature until Voltage() reaches the **Terminate Voltage**. NominalAvailableCapacity() and FullAvailableCapacity() are the uncompensated (no or light load) versions of RemainingCapacity() and FullChargeCapacity() respectively.

<sup>(3)</sup> Display as the value EVSW displayed. Data Flash value is different.

The bq27520-G1 has two flags accessed by the *Flags()* function that warns when the battery's SOC has fallen to critical levels. When *RemainingCapacity()* falls below the first capacity threshold, specified in SO*C1 Set Threshold*, the *[SOC1]* (*State of Charge Initial)* flag is set. The flag is cleared once *RemainingCapacity()* rises above SOC1 Set Threshold. The bq27520-G1's BAT\_LOW pin automatically reflects the status of the *[SOC1]* flag. This flag is enabled when BL\_INT bit in *Operation Configuration B* is set. All units are in mAh.

When *Voltage()* falls below the system shut down threshold voltage, *SysDown Set Volt Threshold*, the *[SYSDOWN]* flag is set, serving as a final warning to shut down the system. The SOC\_INT also signals. When *Voltage()* rises above *SysDown Clear Voltage* and the *[SYSDOWN]* flag has already been set, the *[SYSDOWN]* flag is cleared. The SOC\_INT also signals such change. All units are in mV.

When the voltage is discharged to *Final Voltage*, the *SOC will be set as 0*.

#### 5.2 IMPEDANCE TRACK™ VARIABLES

The bq27520-G1 has several data flash variables that permit the user to customize the Impedance Track™ algorithm for optimized performance. These variables are dependent upon the power characteristics of the application as well as the cell itself.

#### 5.2.1 Load Mode

Load Mode is used to select either the constant-current or constant-power model for the Impedance  $Track^{TM}$  algorithm as used in **Load Select** (see **Load Select**). When **Load Mode** is 0, the **Constant Current Model** is used (default). When 1, the **Constant Power Model** is used. The [LDMD] bit of CONTROL STATUS reflects the status of **Load Mode**.

#### 5.2.2 Load Select

**Load Select** defines the type of power or current model to be used to compute load-compensated capacity in the Impedance Track<sup>TM</sup> algorithm. If **Load Mode** = 0 (*Constant-Current*) then the options presented in Table 5-1 are available.

LoadSelect Value **Current Model Used** Average discharge current from previous cycle: There is an internal register that records the average discharge current through each entire discharge cycle. The previous average is stored in this register. Present average discharge current: This is the average discharge current from the beginning of this discharge cycle 1(default) until present time. Average current: based on AverageCurrent() 3 Current: based off of a low-pass-filtered version of **AverageCurrent()** ( $\tau = 14 \text{ s}$ ) 4 Design capacity / 5: C Rate based off of Design Capacity /5 or a C/5 rate in mA. 5 AtRate (mA): Use whatever current is in AtRate() 6 User\_Rate-mA: Use the value in User\_Rate-mA. This mode provides a completely user-configurable method.

Table 5-1. Constant-Current Model Used When Load Mode = 0

If **Load Mode** = 1 (Constant Power) then the following options shown in Table 5-2 are available



www.ti.com \_\_\_\_\_\_SLUS955-JUNE 2010

### Table 5-2. Constant-Power Model Used When Load Mode = 1

LoadSelect Value	Power Model Used
0	Average discharge power from previous cycle: There is an internal register that records the average discharge power through each entire discharge cycle. The previous average is stored in this register.
1(default)	Present average discharge power: This is the average discharge power from the beginning of this discharge cycle until present time.
2	Average current x voltage: based off the AverageCurrent() and Voltage().
3	Current x voltage: based off of a low-pass-filtered version of <b>AverageCurrent()</b> ( $\tau$ =14 s) and <b>Voltage()</b>
4	Design energy / 5: C Rate based off of Design Energy /5 or a C/5 rate in mA.
5	AtRate (10 mW): Use whatever value is in AtRate( ).
6	User_Rate-10mW: Use the value in <i>User_Rate-10mW</i> . This mode provides a completely user-configurable method.

### 5.2.3 Reserve Cap-mAh

**Reserve Cap-mAh** determines how much actual remaining capacity exists after reaching 0 **RemainingCapacity()**, before **Terminate Voltage** is reached. A no-load rate of compensation is applied to this reserve.

### 5.2.4 Reserve Cap-mWh

**Reserve Cap-mWh** determines how much actual remaining capacity exists after reaching 0 **AvailableEnergy()**, before **Terminate Voltage** is reached. A no-load rate of compensation is applied to this reserve capacity.

### 5.2.5 Dsg Current Threshold

This register is used as a threshold by many functions in the bq27520-G1 to determine if actual discharge current is flowing into or out of the cell. The default for this register is in Table 4-7, which should be sufficient for most applications. This threshold should be set low enough to be below any normal application load current but high enough to prevent noise or drift from affecting the measurement.

### 5.2.6 Chg Current Threshold

This register is used as a threshold by many functions in the bq27520-G1 to determine if actual charge current is flowing into or out of the cell. The default for this register is in Table 4-7, which should be sufficient for most applications. This threshold should be set low enough to be below any normal charge current but high enough to prevent noise or drift from affecting the measurement.

### 5.2.7 Quit Current, DSG Relax Time, CHG Relax Time, and Quit Relax Time

The **Quit Current** is used as part of the Impedance Track™ algorithm to determine when the bq27520-G1 enters relaxation mode from a current-flowing mode in either the charge direction or the discharge direction. The value of *Quit Current* is set to a default value in Table 4-7 and should be above the standby current of the system.

Either of the following criteria must be met to enter relaxation mode:

- | AverageCurrent() | < | Quit Current | for Dsg Relax Time
- | AverageCurrent() | < | Quit Current | for Chg Relax Time

After about 5 minutes in relaxation mode, the bq27520-G1 attempts to take accurate OCV readings. An additional requirement of dV/dt < 4  $\mu$ V/s is required for the bq27520-G1 to perform Qmax updates. These updates are used in the Impedance Track<sup>TM</sup> algorithms. It is critical that the battery voltage be relaxed during OCV readings to and that the current is not be higher than C/20 when attempting to go into relaxation mode.

**Quit Relax Time** specifies the minimum time required for *AverageCurrent()* to remain above the **QuitCurrent** threshold before exiting relaxation mode.



#### 5.2.8 Qmax 0 and Qmax 1

Generically called Qmax, these dynamic variables contain the respective maximum chemical capacity of the active cell profiles, and are determined by comparing states of charge before and after applying the load with the amount of charge passed. They also correspond to capacity at a very low rate of discharge, such as the C/20 rate. For high accuracy, this value is periodically updated by the bq27520-G1 during operation. Based on the battery cell capacity information, the initial value of chemical capacity should be entered in the Qmax n field for each default cell profile. The Impedance Track<sup>TM</sup> algorithm updates these values and maintains them the associated actual cell profiles.

### 5.2.9 Update Status 0 and Update Status 1

Bit 0 (0x01) of the *Update Status* n registers indicates that the bq27520-G1 has learned new Qmax parameters and is accurate. The remaining bits are reserved. Bits 0 is user-configurable; however, it is also a status flag that can be set by the bq27520-G1. Bit 0 should never be modified except when creating a golden image file as explained in the application note Preparing Optimized Default Flash Constants for specific Battery Types (SLUA334). Bit 0 is updated as needed by the bq27520-G1.

### 5.2.10 Avg I Last Run

The bq27520-G1 logs the current averaged from the beginning to the end of each discharge cycle. It stores this average current from the previous discharge cycle in this register. This register should not be modified. It is only updated by the bq27520-G1 when required.

### 5.2.11 Avg P Last Run

The bq27520-G1 logs the power averaged from the beginning to the end of each discharge cycle. It stores this average power from the previous discharge cycle in this register. To get a correct average power reading the bq27520-G1 continuously multiplies instantaneous current times *Voltage()* to get power. It then logs this data to derive the average power. This register should not be modified. It is only updated by the bq27520-G1 when required.

### 5.2.12 Delta Voltage

The bq27520-G1 stores the maximum difference of Voltage() during short load spikes and normal load, so the Impedance Track<sup>TM</sup> algorithm can calculate remaining capacity for pulsed loads. It is not recommended to change this value.

### 5.2.13 Default Ra and Ra Tables

These tables contain encoded data and, with the exception of the **Default Ra Tables**, are automatically updated during device operation. No user changes should be made except for reading/writing the values from a pre-learned pack (part of the process for creating golden image files).

### 5.3 DETAILED PIN DESCRIPTION

### 5.3.1 The Operation Configuration Register

Some bq27520-G1 pins are configured via the *Operation Configuration* data flash register, as indicated in Table 5-3. This register is programmed/read via the methods described in Section 4.2.1, Accessing the Data Flash. The register is located at subclass = 64, offset = 0.



Table 5-3. Operation Configuration Bit Definition

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
High byte	RESCAP	BATG_OVR	INT_BREM	PFC_CFG1	PFC_CFG0	IWAKE	RSNS1	RSNS0
Low byte	INT_FOCV	IDSELEN	SLEEP	RMFCC	SOCI_POL	BATG_POL	BATL_POL	TEMPS

RESCAP = No-load rate of compensation is applied to the reserve capacity calculation. True when set. Default is 0.

BATG\_OVR = BAT\_GD override bit. If the gauge enters Hibernate only due to the cell voltage, the BAT\_GD pin will not negate. True when set. Default is 0.

INT\_BERM = Battery removal interrupt bit. The SOC\_INT pulses 1ms when the battery removal interrupt is enabled. True when set. The default is 0.

PFC\_CFG1/PFC\_CFG0 = Pin function code (PFC) mode selection: PFC 0, 1, or 2 selected by 0/0, 0/1, or 1/0, respectively. Default is PFC 1 (0/1)

IWAKE/RSNS1/RSNS0 = These bits configure the current wake function (see Table 5-7). Default is 0/0/1.

INT\_FOCV = Indication of the measurement of the OCV during the initialization. The SOC\_INT will pulse during the first measurement if this bit is set. True when set. Default is 0.

IDSELEN = Enables cell profile selection feature. True when set. Default is 1.

SLEEP = The fuel gauge can enter sleep, if operating conditions allow. True when set. Default is 1.

RMFCC = RM is updated with the value from FCC, on valid charge termination. True when set. Default is 1.

SOCI POL = SOC interrupt polarity is active-low. True when cleared. Default is 0.

 $BATG_POL = \overline{BAT_GD}$  pin is active-low. True when cleared. Default is 0.

BATL\_POL = BAT\_LOW pin is active-high. True when set. Default is 1.

TEMPS = Selects external thermistor for Temperature() measurements. True when set. Default is 1.

Some bq27520-G1 pins are configured via the **Operation Configuration B** data flash register, as indicated in Table 5-4. This register is programmed/read via the methods described in Section 4.2.1: Accessing the Data Flash. The register is located at subclass = 64, offset = 9.

### Table 5-4. Operation Configuration B Bit Definition

			•	•			
bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
WRTEMP	BIE	BL INT	GNDSEL	RSVD	DFWrIndBL	RFACTSTEP	INDFACRES

WRTEMP = Enables the temperature write. The temperature could be written by the host. True when set. Default is 0.

BIE = Battery insertion detection enable. When the battery insertion detection is disabled, the gauge relies on the host command to set the BAT\_DET bit. True when set. Default is 1.

BL\_INT = Battery low interrupt enable. True when set. Default is 0.

GNDSEL = The ADC ground select control. The Vss (Pin D1) is selected as ground reference when the bit is clear. Pin A1 is selected when the bit is set. Default is 0.

DFWrIndBL = DataFlash Write Indication. SOC\_INT is used for indication if the bit is clear. BAT\_LOW is used for indication if the bit is set. Default is 0.

RFACTSTEP = Enables Ra Step up/down to Min/Max Res Factor before disabling Ra updates. Default is 1.

INDFACRES = Enables SOC\_INT pin to assert during FACTORY\_RESTORE subcommand execution . Default is 1.

### Table 5-5. Operation Configuration C Bit Definition

bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0	
BATGSPUEN	BATGWPUEN	BATLSPUEN	BATLWPUEN	RSVD	SlpWkChg	DeltaVOpt1	DeltaVOpt0	

BATGSPUEN =  $\overline{BAT\_GD}$  pin strong pull-up enable. Default is 0.

BATGWPUEN =  $\overline{BAT}_{GD}$  pin weak pull-up enable. Default is 0.

BATLSPUEN = BAT\_LOW pin strong pull-up enable. Default is 1.

BATLWPUEN = BAT\_LOW pin weak pull-up enable. Default is 0.

SlpWkChg = Enables compensation for the passed charge missed when waking from SLEEP mode. Default is 1.

DeltaVOpt[1:0] = Configures options for determination of **Delta Voltage** which is defined as the maximum difference in **Voltage**() during normal load and short load spikes. **Delta Voltage** is a used as a compensation factor for calculating for **RemainingCapacity**() under pulsed loads. Default is 0/0.

0/0 = Standard DeltaV. Average variance from steady state voltage used to determine end of discharge voltage. (Default)

0/1 = No Averaging. The last instantaneous change in Voltage() from steady state is used to determine the end of discharge voltage.

1/0 = Use the value in *Min Delta Voltage*.

1/1 = Not used.

### 5.3.2 Pin Function Code Descriptions

The bq27520-G1 has three possible pin-function variations that can be selected in accordance with the circuit architecture of the end application. Each variation has been assigned a pin function code, or PFC.

When the PFC is set to 0, only the bq27520-G1 measures battery temperature under discharge and relaxation conditions. The charger does not receive any information from the bq27520-G1 about the temperature readings, and therefore operates open-loop with respect to battery temperature.



A PFC of 1 is like a PFC of 0, except temperature is also monitored during battery charging. If charging temperature falls outside of the preset range defined in data flash, a charger can be disabled via the BAT\_GD pin until cell temperature recovers. See Section 5.6.2, Charge Inhibit and Suspend, for additional details.

Finally when the PFC is set to 2, the battery thermistor can be shared between the fuel gauge and the charger. The charger has full usage of the thermistor during battery charging, while the fuel gauge uses the thermistor exclusively during discharge and battery relaxation.

When PFC = 0 or 2, the bq27520-G1 must be queried by the system in order to determine the battery temperature. At that time, the bq27520-G1 samples the temperature. This saves battery energy when operating from battery, as periodic temperature updates are avoided during charging mode. Note: Due to thermistor sharing limitations, temperature data is not available during battery charging with PFC = 2.

The PFC is specified in *Operation Configuration [PFC\_CFG1, PFC\_CFG0]*. The default is PFC = 1.

### 5.3.3 BAT\_LOW Pin

The BAT\_LOW pin provides a system processor with an electrical indicator of battery status. The signaling on the BAT\_LOW pin follows the status of the [SOC1] bit in the Flags() register. Note that the polarity of the BAT\_LOW pin can be inverted via the [BATL\_POL] bit of Operation Configuration.

## 5.3.4 Power Path Control With the BAT\_GD Pin

The bq27520-G1 must operate in conjunction with other electronics in a system appliance, such as chargers or other ICs and application circuits that draw appreciable power. After a battery is inserted into the system, there should be no charging current or a discharging current higher than C/20, so that an accurate OCV can be read. The OCV is used for helping determine which battery profile to use, as it constitutes part of the battery impedance measurement

When a battery is inserted into a system, the Impedance Track™ algorithm requires that no charging of the battery takes place and that any discharge is limited to less than C/20—these conditions are sufficient for the fuel gauge to take an accurate OCV reading. To disable these functions, the BAT\_GD pin is merely negated from the default setting. Once an OCV reading has be made, the BAT\_GD pin is asserted, thereby enabling battery charging and regular discharge of the battery. The *Operation Configuration* [BATG\_POL] bit can be used to set the polarity of the battery good signal, should the default configuration need to be changed.

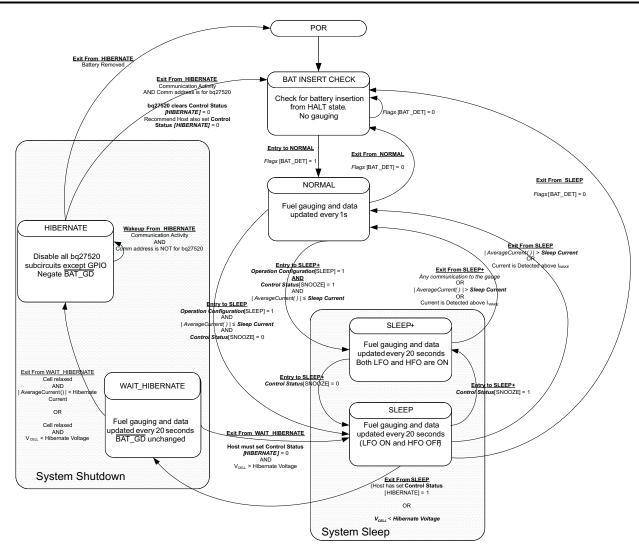


Figure 5-1. Power Mode Diagram

Figure 5-1 details how the BAT\_GD pin functions in the context of battery insertion and removal, as well as NORMAL vs. SLEEP modes.

In PFC 1, the BAT\_GD pin is also used to disable battery charging when the bq27520-G1 reads battery temperatures outside the range defined by [Charge Inhibit Temp Low, Charge Inhibit Temp High]. The BAT\_GD line is asserted once temperature falls within the range [Charge Inhibit Temp Low + Temp Hys, Charge Inhibit Temp High – Temp Hys].

### 5.3.5 Battery Detection Using the BI/TOUT Pin

During power-up or hibernate activities, or any other activity where the bq27520-G1 needs to determine whether a battery is connected or not, the fuel gauge applies a test for battery presence. First, the BI/TOUT pin is put into high-Z status. The weak  $1.8M\Omega$  pull-up resistor will keep the pin high while no battery is present. When a battery is inserted (or is already inserted) into the system device, the BI/TOUT pin will be pulled low. This state is detected by the fuel gauge, which polls this pin every second when the gauge has power. A *battery-disconnected* status is assumed when the bq27520-G1 reads a thermistor voltage that is near 2.5V.





## 5.3.6 SOC\_INT pin

The SOC\_INT pin generates a pulse of different pulse widths under various conditions as indicated by the table below. After initialization only one SOC\_INT pulse will be generated within any given one second time slot and therefore, may indicate multiple event conditions.

Table 5-6. SOC\_INT Pulse Condition and Width

	<b>Enable Condition</b>	Pulse Width	Comment				
SOC_Delta Point	SOC_Delta ≠ 0	1 ms	During charge, when the SOC is greater than (>) the points, 100% - n x SOC_Delta and 100%; During discharge, when the SOC reaches (≤) the points 100% - n x SOC_Delta and 0%; where n is an integer starting from 0 to the number generating SOC no less than 0%				
SOC1 Set	Always	1 ms	When RSOC reached the SOC1 Set or Clear threshold set in the Data				
SOC1 Clear	•		Flash and BL_INT bit in <i>Operation Configuration B</i> is set.				
SysDown Set	Always	1 ms	When the Dettern Veltage resched the Curbana Cot or Clear threshold				
SysDown Clear	Always	1 ms	When the Battery Voltage reached the SysDown Set or Clear thr set in the Data Flash				
State Change	SOC_Delta ≠ 0	1 ms	When there is a state change including charging, discharging and relaxation. This function is disabled when SOC_Delta is set to 0.				
Battery Removal	INT_BREM bit is set in OpConfig AND BIE bit is set	1ms	This function is disabled when BIE is cleared.				
OCV Command	After Initialization	About 165ms. Same as the OCV command execution time period	SOC_INT pulses for the OCV command after the initialization.				
OCV Command	INT_FOCV bit is set in OpConfig	About 165ms. Same as the OCV command execution time period	This command is to generate the SOC_INT pulse during the initialization.				
Data Flash Write	After Initialization AND DFWrIndWaitTime ≠ 0	Programmmable pulse width flash (see comment)	SOC_INT is used to indicate the data flash update. The gauge will wait $\textbf{\textit{DFWrIndWaitTime}}$ times $5\mu s$ after the SOC_INT signal to start the data flash update. This function is disabled if DFWrIndWaitTime is set to 0.				



#### 5.4 TEMPERATURE MEASUREMENT

The bq27520-G1 measures battery temperature via its TS input, in order to supply battery temperature status information to the fuel gauging algorithm and charger-control sections of the gauge. Alternatively, it can also measure internal temperature via its on-chip temperature sensor, but only if the *[TEMPS]* bit of the *Operation Configuration* register is cleared. The *[GNDSEL]* bit of Operation Configuration B register selects the ground reference of the ADC converter for temperature measurement.

Regardless of which sensor is used for measurement, a system processor can request the current battery temperature by calling the *Temperature()* function (see Section 4.1.1, *Standard Data Commands*, for specific information).

The thermistor circuit requires the use of an external NTC 103AT-type thermistor. Additional circuit information for connecting this thermistor to the bq27520-G1 is shown in Section 8, Reference Schematic.

#### 5.5 OVERTEMPERATURE INDICATION

### 5.5.1 Overtemperature: Charge

If during charging, *Temperature()* reaches the threshold of **OT Chg** for a period of **OT Chg Time** and *AverageCurrent()* > **Chg Current Threshold**, then the [OTC] bit of Flags() is set. When Temperature() falls to **OT Chg Recovery**, the [OTC] of Flags() is reset.

If **OT Chg Time** = 0, then the feature is completely disabled.

### 5.5.2 Overtemperature: Discharge

If during discharging, Temperature() reaches the threshold of OT Dsg for a period of OT Dsg Time, and  $AverageCurrent() \le -Dsg$  Current Threshold, then the [OTD] bit of Flags() is set. When Temperature() falls to OT Dsg Recovery, the [OTD] bit of Flags() is reset.

If **OT Dsg Time** = 0, then feature is completely disabled.

### 5.6 CHARGING AND CHARGE-TERMINATION INDICATION

### 5.6.1 Detecting Charge Termination

For proper bq27520-G1 operation, the cell charging voltage must be specified by the user. The default value for this variable is *Charging Voltage* Table 4-7.

The bq27520-G1 detects charge termination when (1) during 2 consecutive periods of *Current Taper Window*, the AverageCurrent() is < *Taper Current*, (2) during the same periods, the accumulated change in capacity > Min Taper Charge / *Current Taper Window*, and (3) *Voltage*() > *Charging Voltage* - *Taper Voltage*. When this occurs, the [CHG] bit of *Flags*() is cleared. Also, if the [RMFCC] bit of *Operation Configuration* is set, then *RemainingCapacity*() is set equal to *FullChargeCapacity*().

### 5.6.2 Charge Inhibit and Suspend

The bq27520-G1 can indicate when battery temperature has fallen below or risen above predefined thresholds *Charge Inhibit Temp Low* or *Charge Inhibit Temp High*, respectively. In this mode, the [CHG\_INT] bit is set and the  $\overline{BAT}_{GD}$  pin is deserted to indicate this condition. The [CHG\_INT] bit is cleared and the  $\overline{BAT}_{GD}$  pin is asserted once the battery temperature returns to the range *[Charge Inhibit Temp Low + Temp Hys, Charge Inhibit Temp High - Temp Hys]*.

When PFC = 1, the bq27520-G1 can indicate when battery temperature has fallen below or risen above predefined thresholds **Suspend Low Temp** or **Suspend High Temp**, respectively. In this mode, the [XCHG] bit is set to indicate this condition. The [XCHG] bit is cleared once the battery temperature returns to the range **[Charge Inhibit Temp Low + Temp Hys, Charge Inhibit Temp High - Temp Hys]**.



The charging should not start when the temperature is below the Charge Inhibit Temp Low or above the Charge Inhibit Temp High. The charging can continue if the charging starts inside the window [Charge Inhibit Temp Low, Charge Inhibit Temp High] until the temperature is either below Suspend Low Temp or above the Suspend Low Temp. Therefore, the window [Charge Inhibit Temp Low, Charge Inhibit Temp High] must be inside the window of [Suspend Low Temp, Suspend High Temp].

#### 5.7 POWER MODES

The bq27520-G1 has different power modes: BAT INSERT CHECK, NORMAL, SLEEP, SLEEP+ and HIBERNATE. In NORMAL mode, the bq27520-G1 is fully powered and can execute any allowable task. In SLEEP+ mode, both low frequency and high frequency oscillators are active. Although the SLEEP+ has higher current consumption than the SLEEP mode, it is also a reduced power mode. In SLEEP mode, the fuel gauge turns off the high frequency oscillator and exists in a reduced-power state, periodically taking measurements and performing calculations. In HIBERNATE mode, the fuel gauge is in a very low power state, but can be woken up by communication or certain I/O activity. Finally, the BAT INSERT CHECK mode is a powered-up, but low-power halted, state, where the bq27520-G1 resides when no battery is inserted into the system.

The relationship between these modes is shown in Figure 5-1.

#### 5.7.1 BAT INSERT CHECK Mode

This mode is a halted-CPU state that occurs when an adapter, or other power source, is present to power the bq27520-G1 (and system), yet no battery has been detected. When battery insertion is detected, a series of initialization activities begin, which include: OCV measurement, setting the BAT\_GD pin, and selecting the appropriate battery profiles.

Some commands, issued by a system processor, can be processed while the bq27520-G1 is halted in this mode. The gauge will wake up to process the command, then return to the halted state awaiting battery insertion.

#### 5.7.2 NORMAL MODE

The fuel gauge is in NORMAL mode when not in any other power mode. During this mode, AverageCurrent(), Voltage() and Temperature() measurements are taken, and the interface data set is updated. Decisions to change states are also made. This mode is exited by activating a different power mode.

Because the gauge consumes the most power in NORMAL mode, the Impedance Track™ algorithm minimizes the time the fuel gauge remains in this mode.

### 5.7.3 SLEEP MODE

SLEEP mode is entered automatically if the feature is enabled (*Operation Configuration [SLEEP]* = 1) and *AverageCurrent()* is below the programmable level *Sleep Current*. Once entry into SLEEP mode has been qualified, but prior to entering it, the bq27520-G1 performs an coulomb counter autocalibration to minimize offset.

During SLEEP mode, the bq27520-G1 periodically takes data measurements and updates its data set. However, a majority of its time is spent in an idle condition.

The bq27520-G1 exits SLEEP if any entry condition is broken, specifically when (1) *AverageCurrent()* rises above *Sleep Current*, or (2) a current in excess of  $I_{WAKE}$  through  $R_{SENSE}$  is detected.

In the event that a battery is removed from the system while a charger is present (and powering the gauge), Impedance  $Track^{TM}$  updates are not necessary. Hence, the fuel gauge enters a state that checks for battery insertion and does not continue executing the Impedance  $Track^{TM}$  algorithm.



#### 5.7.4 SLEEP+ MODE

Compared to the SLEEP mode, SLEEP+ mode has the high frequency oscillator in operation. The communication delay could be eliminated. The SLEEP+ is entered automatically if the feature is enabled (CONTROL STATUS [SNOOZE] = 1) and AverageCurrent() is below the programmable level Sleep Current.

During SLEEP+ mode, the bq27520-G1 periodically takes data measurements and updates its data set. However, a majority of its time is spent in an idle condition.

The bq27520-G1 exits SLEEP+ if any entry condition is broken, specifically when (1) any communication activity with the gauge, or (2) AverageCurrent() rises above Sleep Current(), or (3) a current in excess of  $I_{WAKE}$  through  $R_{SENSE}$  is detected.

### 5.7.5 HIBERNATE MODE

HIBERNATE mode should be used when the system equipment needs to enter a low-power state, and minimal gauge power consumption is required. This mode is ideal when a system equipment is set to its own HIBERNATE, SHUTDOWN, or OFF modes.

Before the fuel gauge can enter HIBERNATE mode, the system must set the [HIBERNATE] bit of the CONTROL\_STATUS register. The gauge waits to enter HIBERNATE mode until it has taken a valid OCV measurement and the magnitude of the average cell current has fallen below *Hibernate Current*. The gauge can also enter HIBERNATE mode if the cell voltage falls below *Hibernate Voltage* and a valid OCV measurement has been taken. The gauge will remain in HIBERNATE mode until the system issues a direct I<sup>2</sup>C command to the gauge or a POR occurs. I<sup>2</sup>C Communication that is not directed to the gauge will not wake the gauge.

It is important that  $\overline{BAT\_GD}$  be deserted status (no battery charging/discharging). This prevents a charger application from inadvertently charging the battery before an OCV reading can be taken. It is the system's responsibility to wake the bq27520-G1 after it has gone into HIBERNATE mode. After waking, the gauge can proceed with the initialization of the battery information (OCV, profile selection, etc.)

### 5.8 POWER CONTROL

### 5.8.1 WAKE-UP COMPARATOR

The wake up comparator is used to indicate a change in cell current while the bq27520-G1 is in SLEEP mode. *Operation Configuration* uses bits *[RSNS1–RSNS0]* to set the sense resistor selection. *Operation Configuration* also uses the *[IWAKE]* bit to select one of two possible voltage threshold ranges for the given sense resistor selection. An internal interrupt is generated when the threshold is breached in either the charge or discharge direction. Setting both *[RSNS1]* and *[RSNS0]* to 0 disables this feature.

RSNS1	RSNS0	IWAKE	Vth(SRP-SRN)
0	0	0	Disabled
0	0	1	Disabled
0	1	0	1.0 mV or –1.0 mV
0	1	1	2.2 mV or –2.2 mV
1	0	0	2.2 mV or –2.2 mV
1	0	1	4.6 mV or –4.6 mV
1	1	0	4.6 mV or –4.6 mV
1	1	1	9.8 mV or –9.8 mV

<sup>(1)</sup> The actual resistance value vs the setting of the sense resistor is not important, just the actual voltage threshold when calculating the configuration. The voltage thresholds are typical values under room temperature.

### 5.8.2 FLASH UPDATES

Data Flash can only be updated if  $Voltage() \ge Flash Update OK Voltage$ . Flash programming current can cause an increase in LDO dropout. The value of *Flash Update OK Voltage* should be selected such that the bq27520-G1 V<sub>CC</sub> voltage does not fall below its minimum of 2.4 V during Flash write operations.

#### 5.9 AUTOCALIBRATION

The bq27520-G1 provides an autocalibration feature that measures the voltage offset error across SRP and SRN as operating conditions change. It subtracts the resulting offset error from normal sense resistor voltage,  $V_{SR}$ , for maximum measurement accuracy.

Autocalibration of the coulomb counter begins on entry to SLEEP mode, except if Temperature() is  $\leq 5^{\circ}C$  or  $Temperature() \geq 45^{\circ}C$ .

The fuel gauge also performs a single offset when (1) the condition of  $AverageCurrent() \le 100$  mA and (2) {voltage change since last offset calibration  $\ge 256$  mV} or {temperature change since last offset calibration is greater than  $80^{\circ}$ C for  $\ge 60$  s}.

Capacity and current measurements continue at the last measured rate during the offset calibration when these measurements cannot be performed. If the battery voltage drops more than 32 mV during the offset calibration, the load current has likely increased; hence, the offset calibration is aborted.

#### 6 APPLICATION-SPECIFIC INFORMATION

### 6.1 BATTERY PROFILE STORAGE AND SELECTION

#### 6.1.1 Common Profile Aspects

When a battery pack is removed from host equipment, the bq27520-G1 maintains some of the battery information in case the battery is re-inserted. This way, the Impedance Track™ algorithm has a means of recovering battery-status information, thereby maintaining good state-of-charge (SOC) estimates.

Two default battery profiles are available to store battery information. They are used to provide the Impedance Track™ algorithm with the default information on two possible battery types expected to be used with the end-equipment. These default profiles can be used to support batteries of different chemistry, same chemistry but different capacities, or same chemistry but different models. Default profiles are programmed by the end-equipment manufacturer. However, only one of the default profiles can be selected, and this selection cannot be changed during end-equipment operation.

In addition to the default profiles, the fuel gauge maintains two profiles PACK0 and PACK1. These tables hold dynamic battery data, and keep track of the status for up to two of the most recent batteries used. In most cases, the fuel gauge can manage the information on two removable battery packs.



### 6.1.2 Activities Upon Pack Insertion

### 6.1.2.1 First OCV and Impedance Measurement

At power-up the  $\overline{BAT\_GD}$  pin is inactive, so that the system might not obtain power from the battery (this depends on actual implementation). In this state, the battery should be put in a condition with load current less than C/20. Next, the bq27520-G1 measures its first open-circuit voltage (OCV) via the BAT pin. The [OCVCMDCOMP] bit will set once the OCV measurement is completed. Depending on the load current, the [OCVFAIL] bit indicates whether the OCV reading is valid. From the OCV(SOC) table, the SOC of the inserted battery is found. Then the  $\overline{BAT\_GD}$  pin is made active, and the impedance of the inserted battery is calculated from the measured voltage and the load current: Z(SOC) = (OCV(SOC) - V) / I. This impedance is compared with the impedance of the dynamic profiles, **Packn**, and the default profiles, **Defn**, for the same SOC (the letter **n** depicts either a **0** or **1**). The [INITCOMP] bit will be set afterwards and the OCV command could be issued

### 6.1.3 Reading Application Status

The *Application Status* data flash location contains cell profile status information, and can be read using the *ApplicationStatus()* extended command (0x6a). The bit configuration of this function/location is shown in Table 6-1.

Table 6-1. ApplicationStatus() Bit Definitions.

Application Configuration	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
Byte	_	_	_	_		_	_	LU_ PROF

LU\_PROF = Last profile used by fuel gauge. Cell0 last used when cleared. Cell1 last used when set. Default is 0.

### 6.2 APPLICATION-SPECIFIC FLOW AND CONTROL

The bq27520-G1 supports only one type of battery profile. This profile is stored in both the **Def0** and **Def1** profiles. When a battery pack is inserted for the first time, the default profile is copied into the **Packn** profiles. Then the Impedance Track<sup>TM</sup> algorithm begins gas gauging, regularly updating **Packn** as the battery is used.

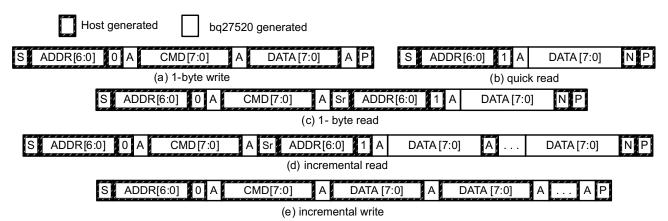
When an existing pack is removed from the bq27520-G1 and a different (or same) pack is inserted, cell impedance is measured immediately after battery detection (see Section 6.1.2.1., First OCV and Impedance Measurement). The bq27520-G1 chooses the profile which is closest to the measured impedance, starting with the **Packn** profiles. That is, if the measured impedance matches **Pack0**, then the **Pack0** profile is used. If the measured impedance matches **Pack1**, then the **Pack1** profile is used. If the measured impedance does not match the impedance stored in either **Pack0** or **Pack1**, the battery pack is deemed new (none of the previously used packs). Either **Def0/Def1** profile is copied into either the **Pack0** or **Pack1** profile, overwriting the oldest **Packn** profile.



### 7 COMMUNICATIONS

### 7.1 I<sup>2</sup>C INTERFACE

The bq27520-G1 supports the standard  $I^2C$  read, incremental read, quick read, one byte write, and incremental write functions. The 7 bit device address (ADDR) is the most significant 7 bits of the hex address and is fixed as 1010101. The first 8-bits of the I2C protocol will; therefore, be 0xAA or 0xAB for write or read, respectively.

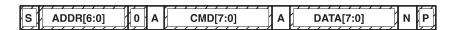


(S = Start, Sr = Repeated Start, A = Acknowledge, N = No Acknowledge, and P = Stop).

The "quick read" returns data at the address indicated by the address pointer. The address pointer, a register internal to the I<sup>2</sup>C communication engine, will increment whenever data is acknowledged by the bq27520-G1 or the I<sup>2</sup>C master. "Quick writes" function in the same manner and are a convenient means of sending multiple bytes to consecutive command locations (such as two-byte commands that require two bytes of data)

The following command sequences are not supported:

Attempt to write a read-only address (NACK after data sent by master):



Attempt to read an address above 0x6B (NACK command):





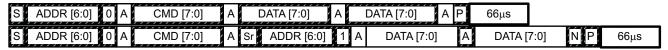
### 7.2 I2C Time Out

The  $I^2C$  engine will release both SDA and SCL if the  $I^2C$  bus is held low for the time defined by  $f^2C$  *Timeout* times 0.5 second. If the bq27520-G1 was holding the lines, releasing them will free for the master to drive the lines. If an external condition is holding either of the lines low, the  $I^2C$  engine will enter the low power sleep mode.

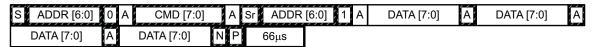
### 7.3 I<sup>2</sup>C Command Waiting Time

To make sure the correct results of a command with the 400KHz I<sup>2</sup>C operation, a proper waiting time should be added between issuing command and reading results. For subcommands, the following diagram shows the waiting time required between issuing the control command the reading the status with the exception of checksum and OCV commands. A 100ms waiting time is required between the checksum command and reading result, and a 1.2 second waiting time is required between the OCV command and result. For read-write standard command, a minimum of 2 seconds is required to get the result updated. For read-only standard commands, there is no waiting time required, but the host should not issue all standard commands more than two times per second. Otherwise, the gauge could result in a reset issue due to the expiration of the watchdog timer.

The I<sup>2</sup>C clock stretch could happen in a typical application. A maximum 80ms clock stretch could be observed during the flash updates. There is up to 270ms clock stretch after the OCV command is issued.



Waiting time between control subcommand and reading results

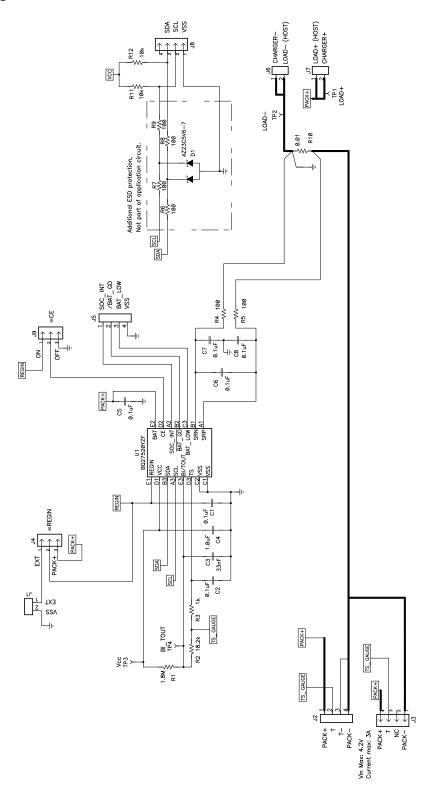


Waiting time between continuous reading results

## TEXAS INSTRUMENTS

# **8 REFERENCE SCHEMATICS**

## 8.1 SCHEMATIC





# 8.2 Package Dimensions

D	E
Max = 2640μm	Max = 1986μm
Min = 2580μm	Min = 1926μm



## PACKAGE OPTION ADDENDUM

1-Jul-2010

#### **PACKAGING INFORMATION**

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
BQ27520YZFR-G1	ACTIVE	DSBGA	YZF	15	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	Purchase Samples
BQ27520YZFT-G1	ACTIVE	DSBGA	YZF	15	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	Purchase Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## PACKAGE MATERIALS INFORMATION

www.ti.com 7-Jan-2011

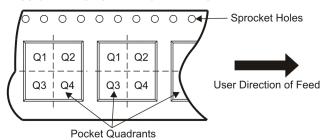
## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

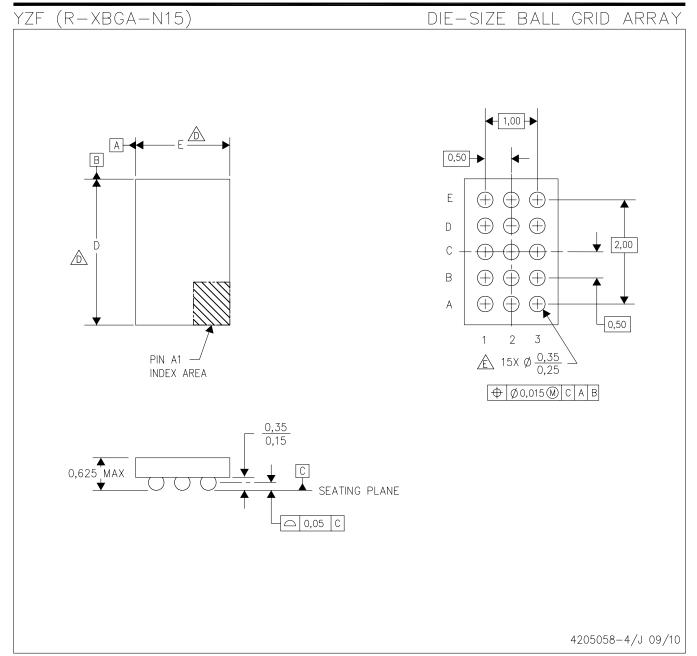
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ27520YZFR-G1	DSBGA	YZF	15	3000	180.0	8.4	2.1	2.76	0.73	4.0	8.0	Q1
BQ27520YZFR-G1	DSBGA	YZF	15	3000	177.8	8.4	2.1	2.76	0.81	4.0	8.0	Q1
BQ27520YZFT-G1	DSBGA	YZF	15	250	177.8	8.4	2.1	2.76	0.81	4.0	8.0	Q1
BQ27520YZFT-G1	DSBGA	YZF	15	250	180.0	8.4	2.1	2.76	0.73	4.0	8.0	Q1

www.ti.com 7-Jan-2011



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ27520YZFR-G1	DSBGA	YZF	15	3000	190.5	212.7	31.8
BQ27520YZFR-G1	DSBGA	YZF	15	3000	220.0	220.0	34.0
BQ27520YZFT-G1	DSBGA	YZF	15	250	220.0	220.0	34.0
BQ27520YZFT-G1	DSBGA	YZF	15	250	190.5	212.7	31.8



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree TM package configuration.

The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product datasheet please contact a local TI representative. A range of possible values per each package desginator can be found at http://www.ti.com/sc/docs/psheets/type/dsbga.html

- E. Reference Product Data Sheet for array population.  $3\times 3$  matrix pattern is shown for illustration only.
- F. This package contains Pb-free balls.

NanoFree is a trademark of Texas Instruments.



#### IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
DSP	dsp.ti.com	Industrial	www.ti.com/industrial
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Security	www.ti.com/security
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com	Wireless	www.ti.com/wireless-apps
RF/IF and ZigBee® Solutions	www.ti.com/lprf		

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated

e2e.ti.com

**TI E2E Community Home Page**